

Photonic microwave oscillators

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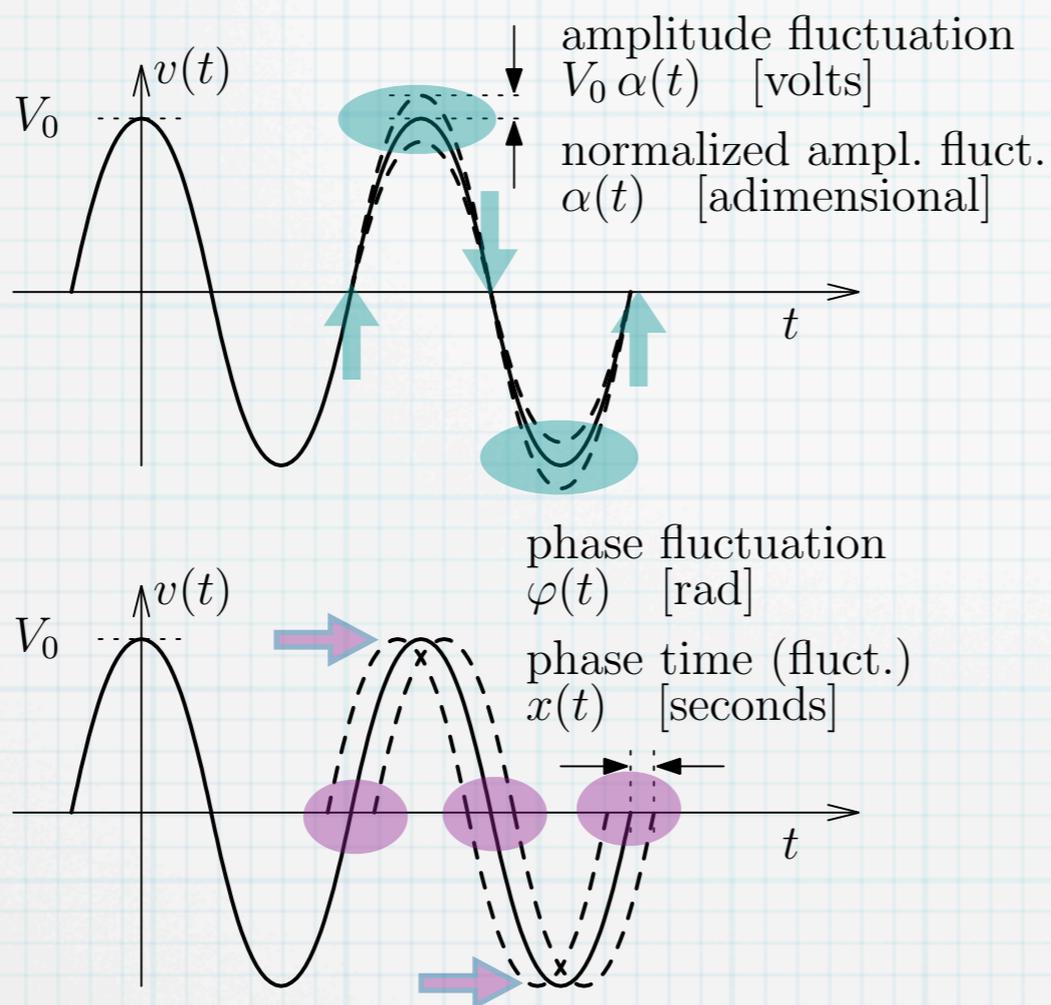
Outline

- * Phase noise and frequency stability
- * Delay-line instrument
- * Correlation instrument
- * Delay line oscillator
- * Nonlinear AM oscillations
- * Optical resonators

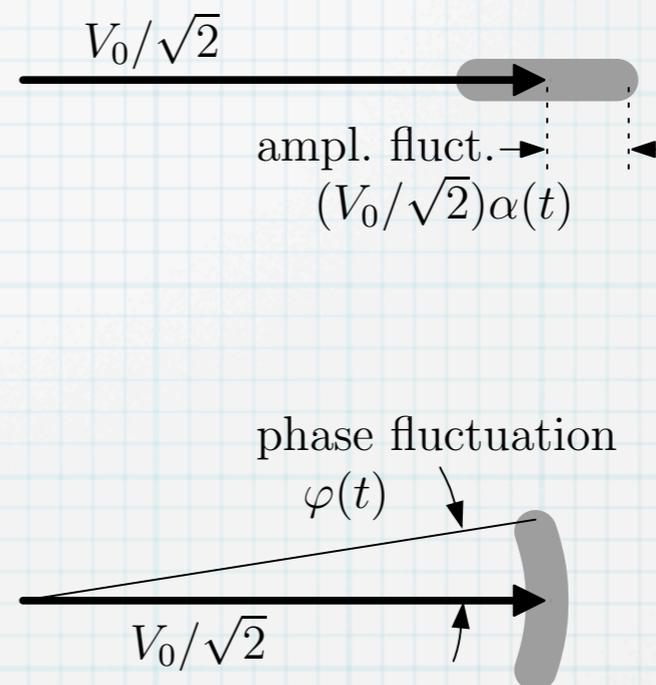
home page <http://rubiola.org>

Phase and amplitude noise

Time Domain



Phasor Representation



polar coordinates

$$v(t) = V_0 [1 + \alpha(t)] \cos [\omega_0 t + \varphi(t)]$$

Cartesian coordinates

$$v(t) = V_0 \cos \omega_0 t + n_c(t) \cos \omega_0 t - n_s(t) \sin \omega_0 t$$

under low noise approximation

$$|n_c(t)| \ll V_0 \quad \text{and} \quad |n_s(t)| \ll V_0$$

It holds that

$$\alpha(t) = \frac{n_c(t)}{V_0} \quad \text{and} \quad \varphi(t) = \frac{n_s(t)}{V_0}$$

Phase noise & friends

random phase fluctuation

$$S_\varphi(f) = \text{PSD of } \varphi(t)$$

power spectral density

it is measured as

$$S_\varphi(f) = \mathbb{E} \{ \Phi(f) \Phi^*(f) \}$$

$$S_\varphi(f) \approx \langle \Phi(f) \Phi^*(f) \rangle_m$$

$$\mathcal{L}(f) = \frac{1}{2} S_\varphi(f) \text{ dBc}$$

random fractional-frequency fluctuation

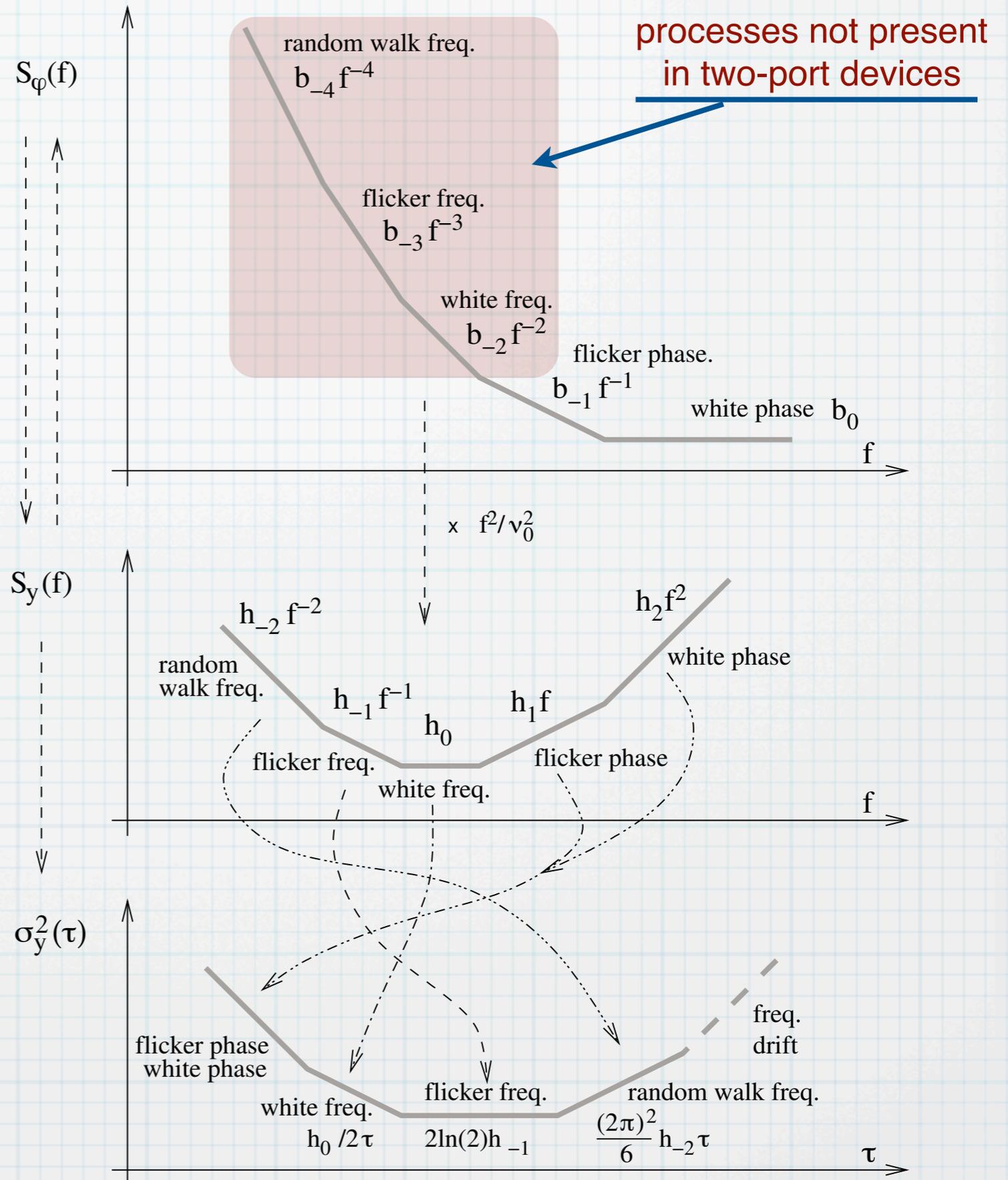
$$y(t) = \frac{\dot{\varphi}(t)}{2\pi\nu_0} \Rightarrow S_y = \frac{f^2}{\nu_0^2} S_\varphi(f)$$

Allan variance

(two-sample wavelet-like variance)

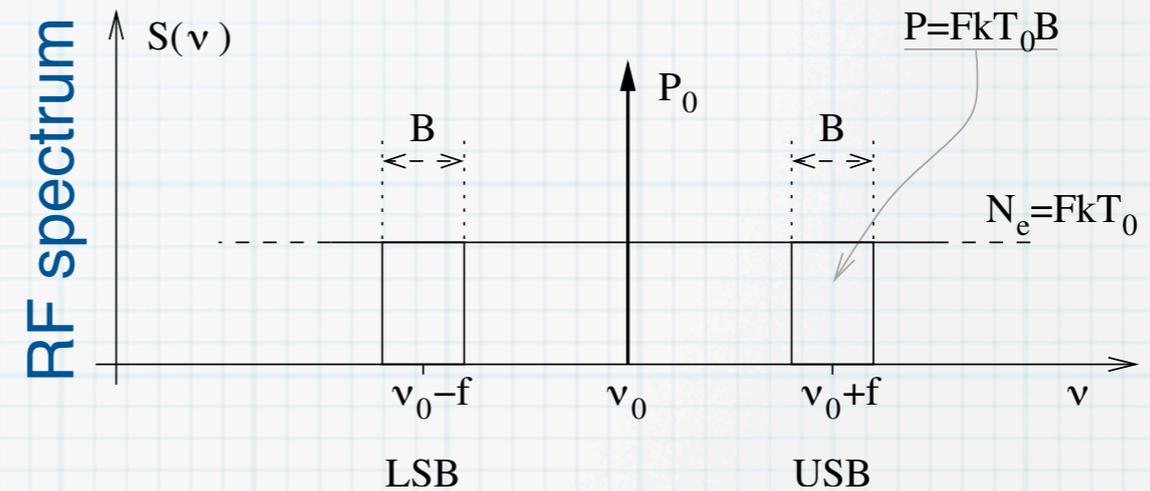
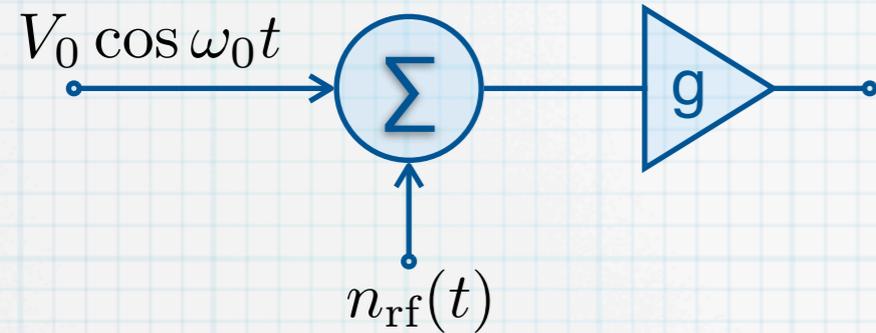
$$\sigma_y^2(\tau) = \mathbb{E} \left\{ \frac{1}{2} \left[\bar{y}_{k+1} - \bar{y}_k \right]^2 \right\} .$$

approaches a half-octave bandpass filter (for white), hence it converges for processes steeper than 1/f



Amplifier white noise

Noise figure F , Input power P_0

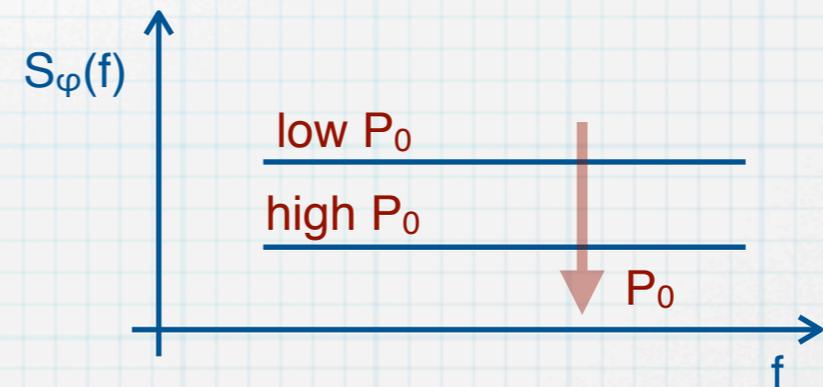


power law

$$S_\varphi = \sum_{i=-4}^0 b_i f^i$$

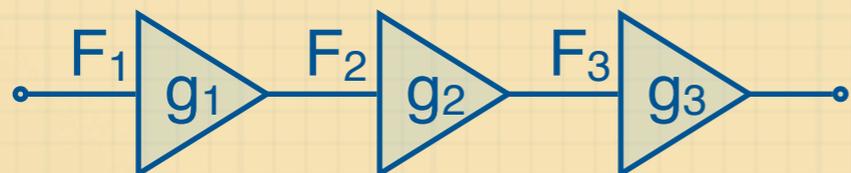
white
phase noise

$$b_0 = \frac{F k T_0}{P_0}$$



Cascaded amplifiers (Friis formula)

The (phase) noise is chiefly that of the 1st stage



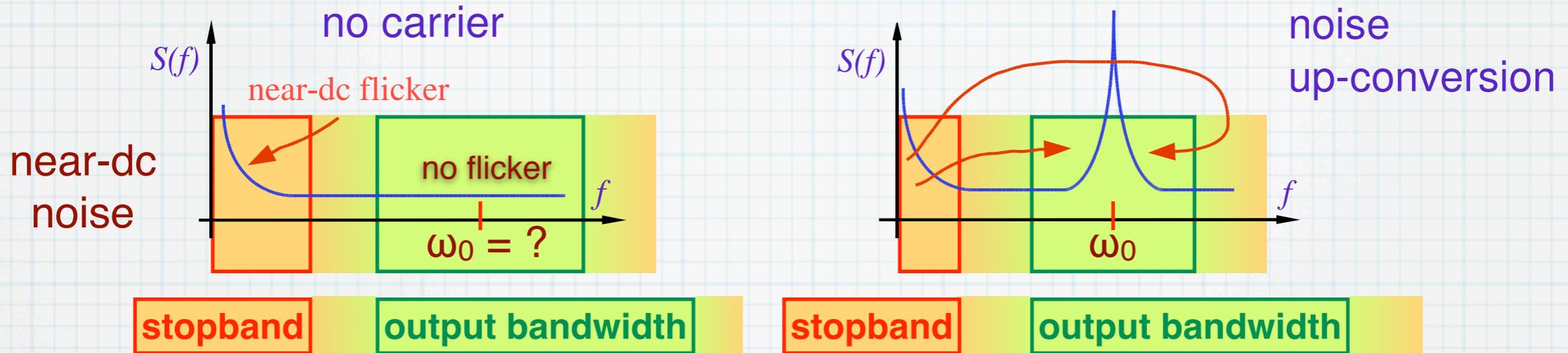
$$N = F_1 k T_0 + \frac{(F_2 - 1) k T_0}{g_1^2} + \dots$$

H. T. Friis, Proc. IRE **32** p.419-422, jul 1944

The Friis formula applied to phase noise

$$b_0 = \frac{F_1 k T_0}{P_0} + \frac{(F_2 - 1) k T_0}{P_0 g_1^2} + \dots$$

Amplifier flicker noise



carrier **near-dc noise**

$$v_i(t) = V_i e^{j\omega_0 t} + n'(t) + jn''(t)$$

the parametric nature of 1/f noise is hidden in n' and n''

substitute
(careful, this hides the down-conversion)

$$v_o(t) = a_1 v_i(t) + a_2 v_i^2(t) + \dots$$

non-linear (parametric) amplifier

expand and select the ω_0 terms

$$v_o(t) = V_i \left\{ a_1 + 2a_2 [n'(t) + jn''(t)] \right\} e^{j\omega_0 t}$$

The noise sidebands are proportional to the input carrier

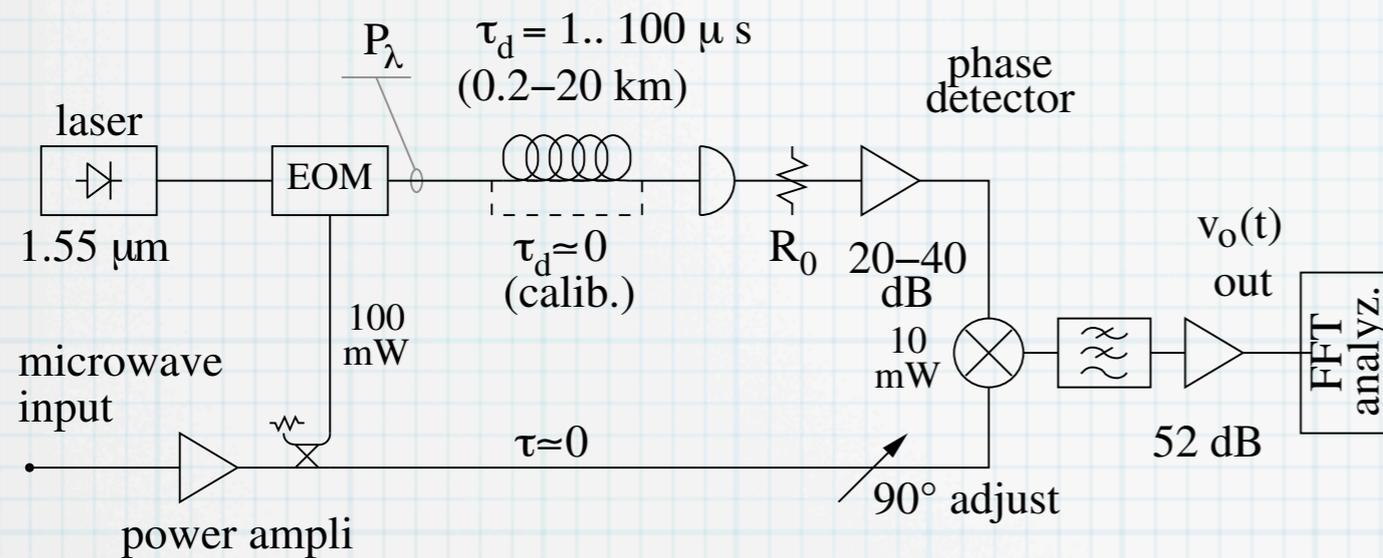
get AM and PM noise

$$\alpha(t) = 2 \frac{a_2}{a_1} n'(t) \quad \varphi(t) = 2 \frac{a_2}{a_1} n''(t)$$

The AM and the PM noise are independent of V_i , thus of power

Delay line theory

Rubiola-Salik-Huang-Yu-Maleki, JOSA-B 22(5) p.987–997 (2005)



Note that here one arm is a microwave cable

Laplace transforms

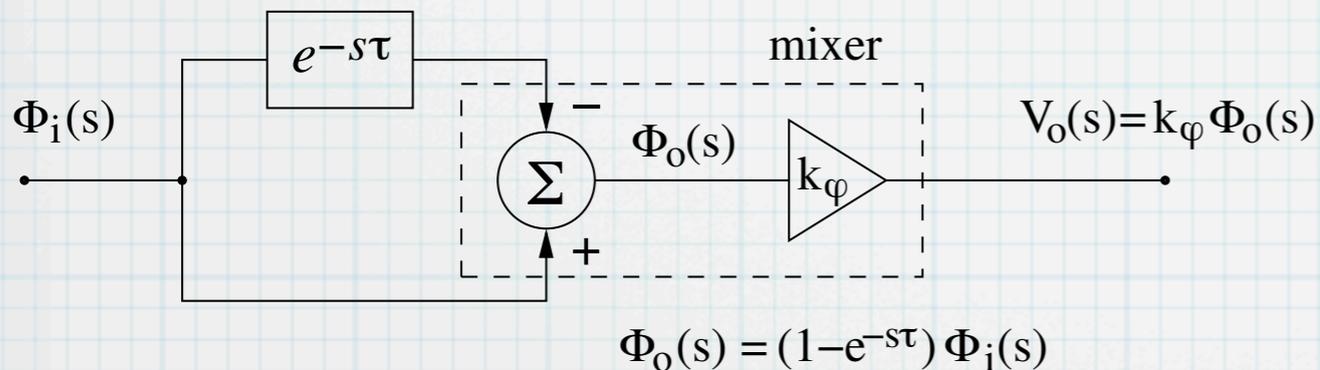
$$\Phi(s) = H_\varphi(s) \Phi_i(s)$$

$$|H_\varphi(f)|^2 = 4 \sin^2(\pi f \tau)$$

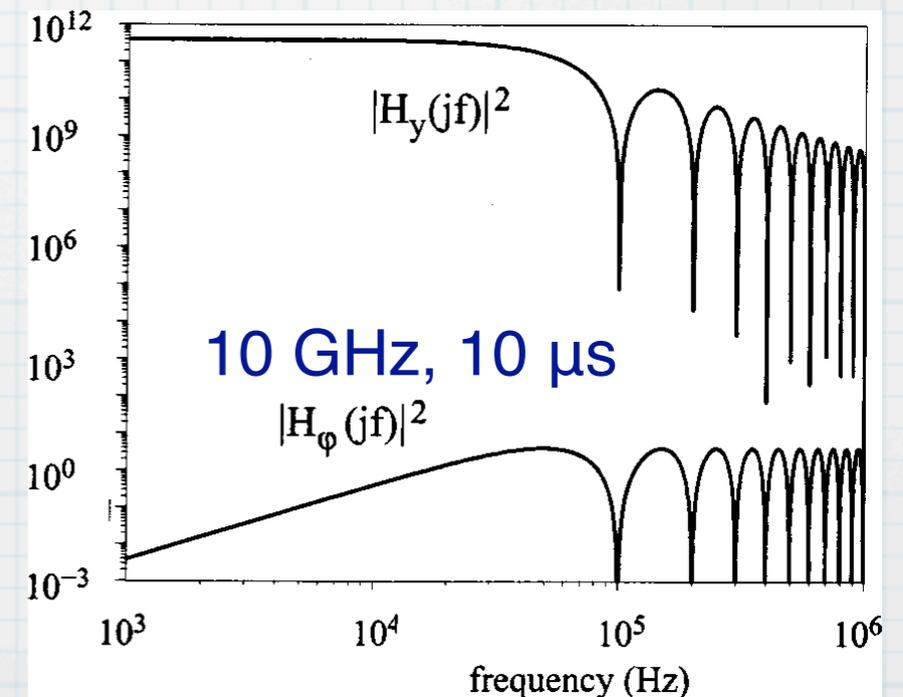
$$S_y(f) = |H_y(f)|^2 S_{\varphi i}(s)$$

$$|H_y(f)|^2 = \frac{4\nu_0^2}{f^2} \sin^2(\pi f \tau)$$

Laplace transforms



- delay → frequency-to-phase conversion
- works at any frequency
- long delay (microseconds) is necessary for high sensitivity
- the delay line must be an optical fiber
 fiber: attenuation 0.2 dB/km, thermal coeff. $6.8 \cdot 10^{-6}/\text{K}$
 cable: attenuation 0.8 dB/m, thermal coeff. $\sim 10^{-3}/\text{K}$



White noise

intensity modulation

$$P(t) = \bar{P}(1 + m \cos \omega_{\mu} t)$$

photocurrent

$$i(t) = \frac{q\eta}{h\nu} \bar{P}(1 + m \cos \omega_{\mu} t)$$

microwave power

$$\bar{P}_{\mu} = \frac{1}{2} m^2 R_0 \left(\frac{q\eta}{h\nu} \right)^2 P^2$$

shot noise

$$N_s = 2 \frac{q^2 \eta}{h\nu} \bar{P} R_0$$

thermal noise

$$N_t = FkT_0$$

total white noise
(one detector)

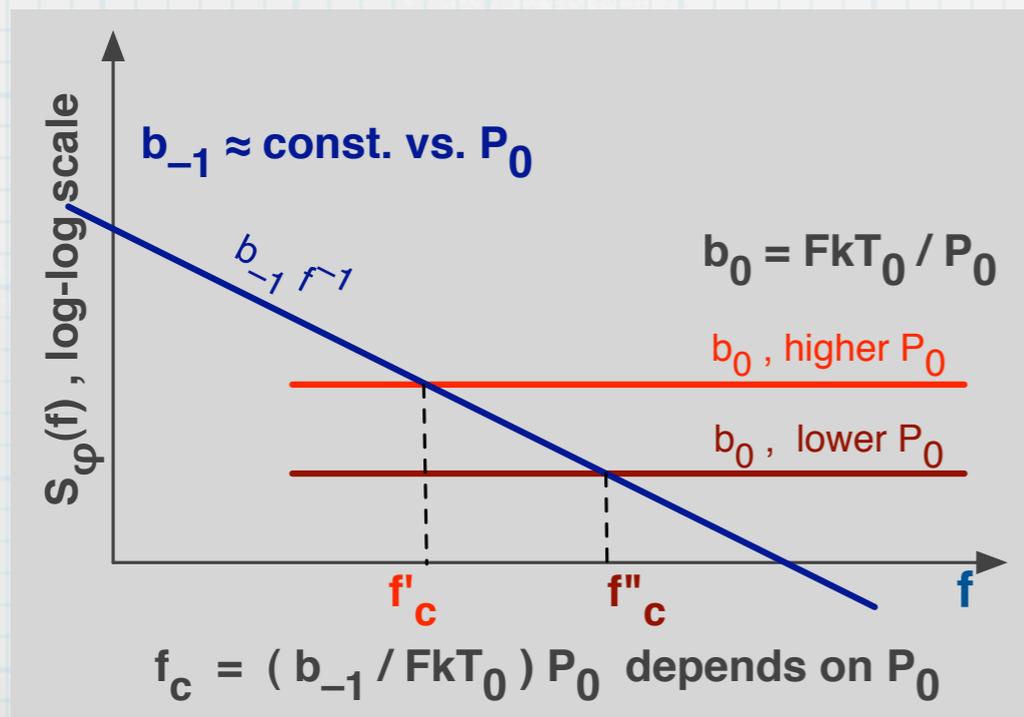
$$S_{\varphi 0} = \frac{2}{m^2} \left[\overset{\text{shot}}{2 \frac{h\nu_{\lambda}}{\eta} \frac{1}{\bar{P}}} + \overset{\text{thermal}}{\frac{FkT_0}{R_0} \left(\frac{h\nu_{\lambda}}{q\eta} \right)^2 \left(\frac{1}{\bar{P}} \right)^2} \right]$$

total white noise
(P/2 each detector)

$$S_{\varphi 0} = \frac{16}{m^2} \left[\frac{h\nu_{\lambda}}{\eta} \frac{1}{\bar{P}} + \frac{FkT_0}{R_0} \left(\frac{h\nu_{\lambda}}{q\eta} \right)^2 \left(\frac{1}{\bar{P}} \right)^2 \right]$$

Flicker (1/f) noise

- * experimentally determined (takes skill, time and patience)
- * amplifier GaAs: $b_{-1} \approx -100$ to -110 dBrad²/Hz,
SiGe: $b_{-1} \approx -120$ dBrad²/Hz
- * photodetector $b_{-1} \approx -120$ dBrad²/Hz
Rubiola & al. IEEE Trans. MTT (& JLT) 54 (2) p.816–820 (2006)
- * mixer $b_{-1} \approx -120$ dBrad²/Hz
- * contamination from AM noise (delay => de-correlation => no sweet point
(Rubiola-Boudot, IEEE Transact UFFC 54(5) p.926–932 (2007))
- * **optical fiber**
- * The phase flicker coefficient b_{-1} is about independent of power
- * in a cascade, $(b_{-1})_{\text{tot}}$ adds up, regardless of the device order



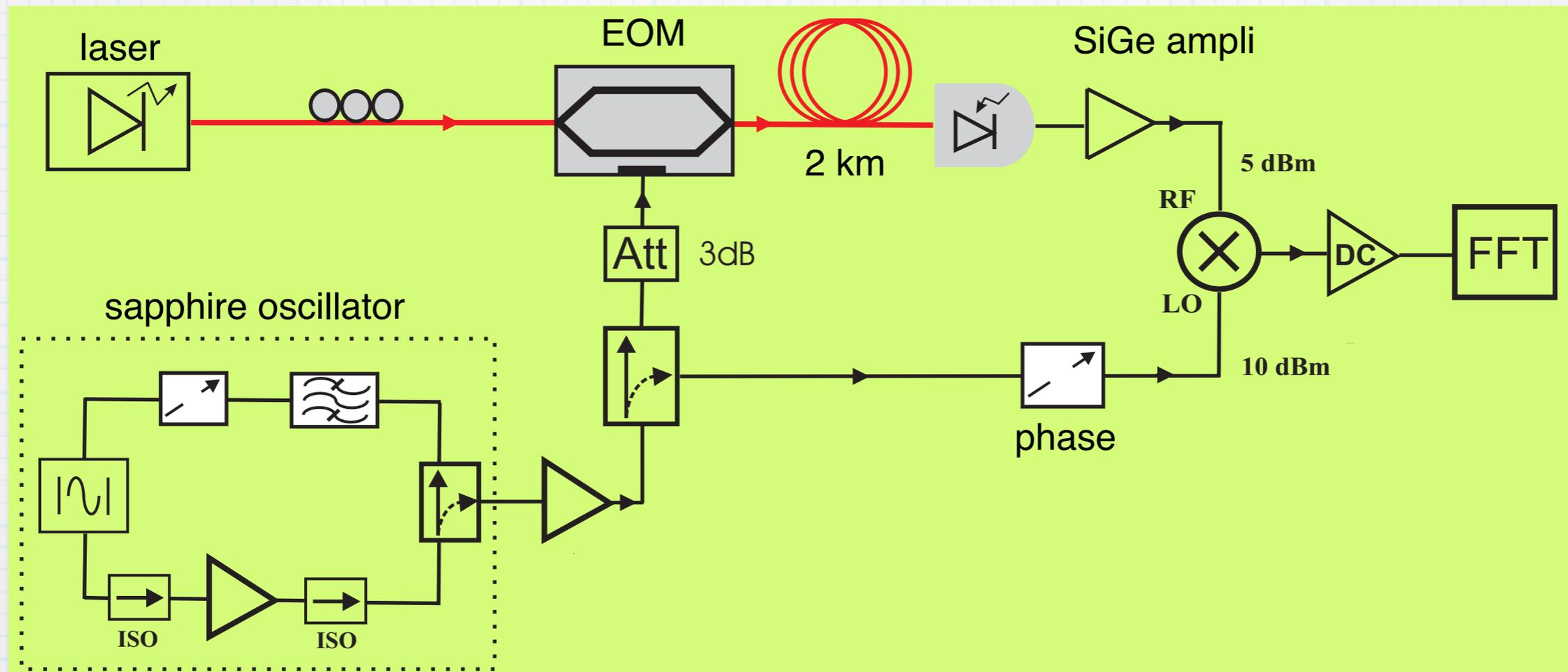
The Friis formula applies to white phase noise

$$b_0 = \frac{F_1 k T_0}{P_0} + \frac{(F_2 - 1) k T_0}{P_0 g_1^2} + \dots$$

In a cascade, the 1/f noise just adds up

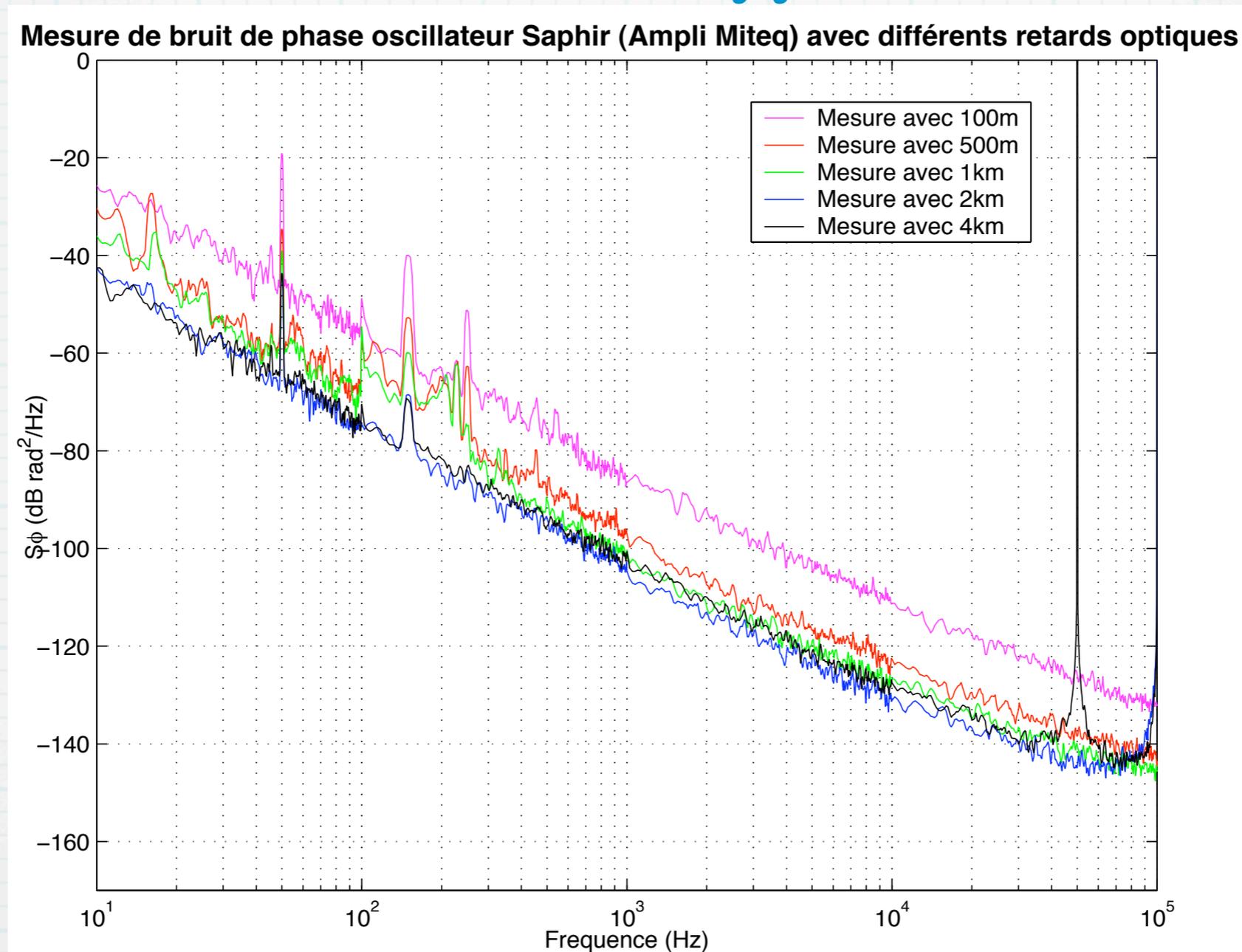
$$(b_{-1})_{\text{tot}} = \sum_{i=1}^m (b_{-1})_i$$

Single-channel instrument



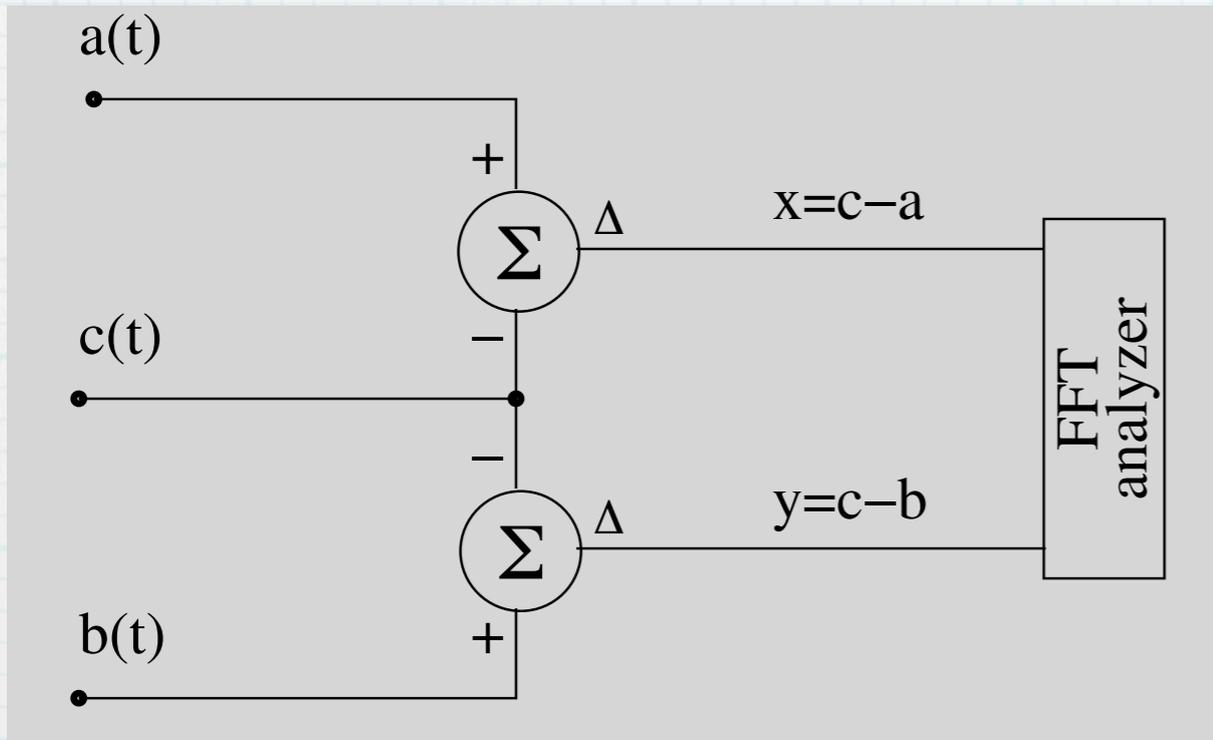
- The laser RIN can limit the instrument sensitivity
- In some cases, the AM noise of the oscillator under test turns into a serious problem (got in trouble with an Anritsu synthesizer)

Measurement of a sapphire oscillator



- The instrument noise scales as $1/\tau$, yet the blue and black plots overlap
magenta, red, green \Rightarrow instrument noise
blue, black \Rightarrow noise of the sapphire oscillator under test
- We can measure the $1/f^3$ phase noise (frequency flicker) of a 10 GHz sapphire oscillator (the lowest-noise microwave oscillator)
- Low AM noise of the oscillator under test is necessary

Basics of correlation spectrum measurements



phase noise measurements		
DUT noise, normal use	a, b c	instrument noise DUT noise
background, ideal case	a, b c = 0	instrument noise no DUT
background, with AM noise	a, b c ≠ 0	instrument noise AM-to-DC noise

$$S_{yx} = \mathbb{E} \{ Y X^* \}$$

W. K. theorem

$$S_{yx} = \langle Y X^* \rangle_m$$

measured, m samples

a , b and c are incorrelated

expand $X = C - A$ and $Y = C - B$

$$S_{yx} = S_{cc}$$

a , b , c independent

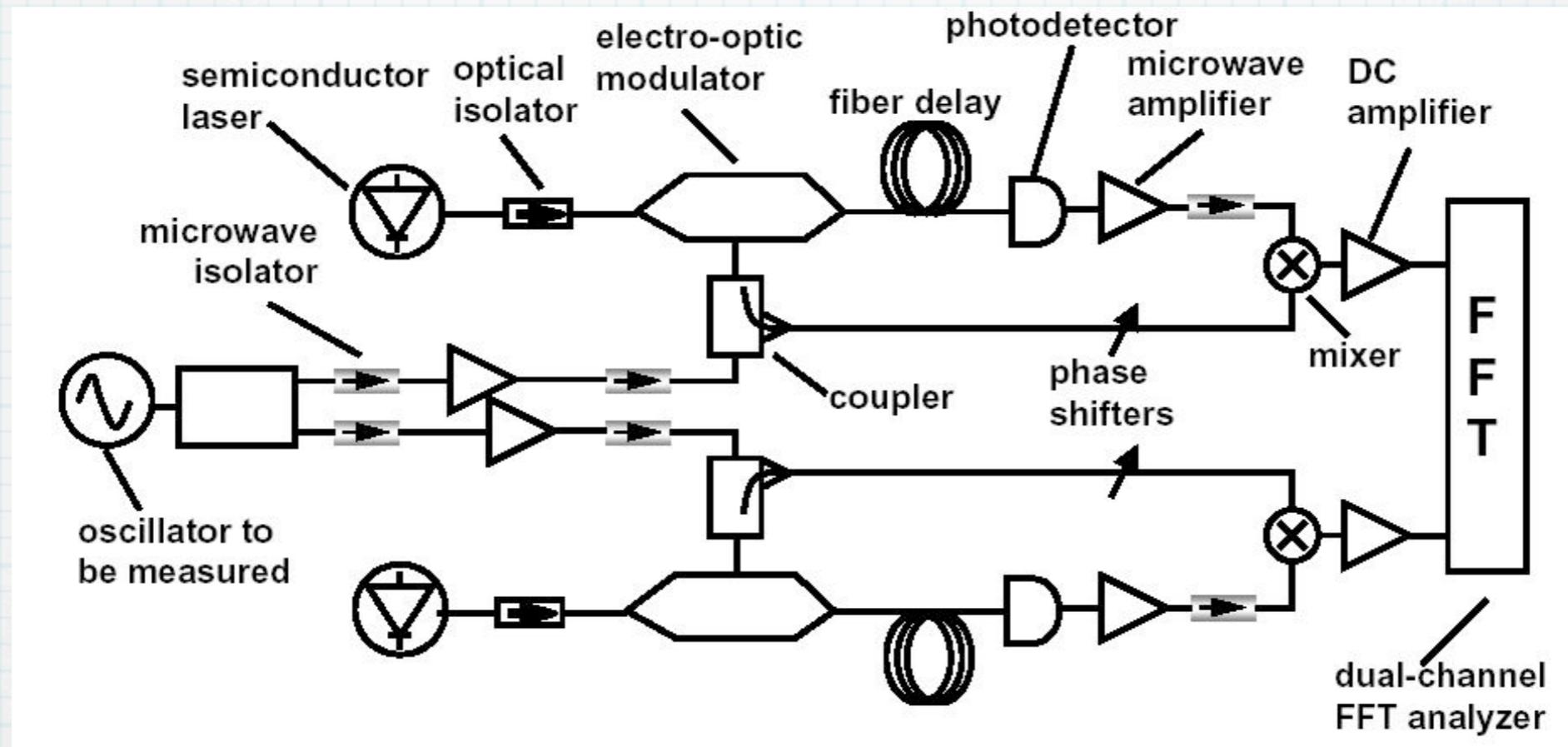
$$S_{yx} = S_{cc} + O(\sqrt{1/m})$$

measured, m samples

Averaging on a sufficiently large number m of spectra is necessary to reject the single-channel noise

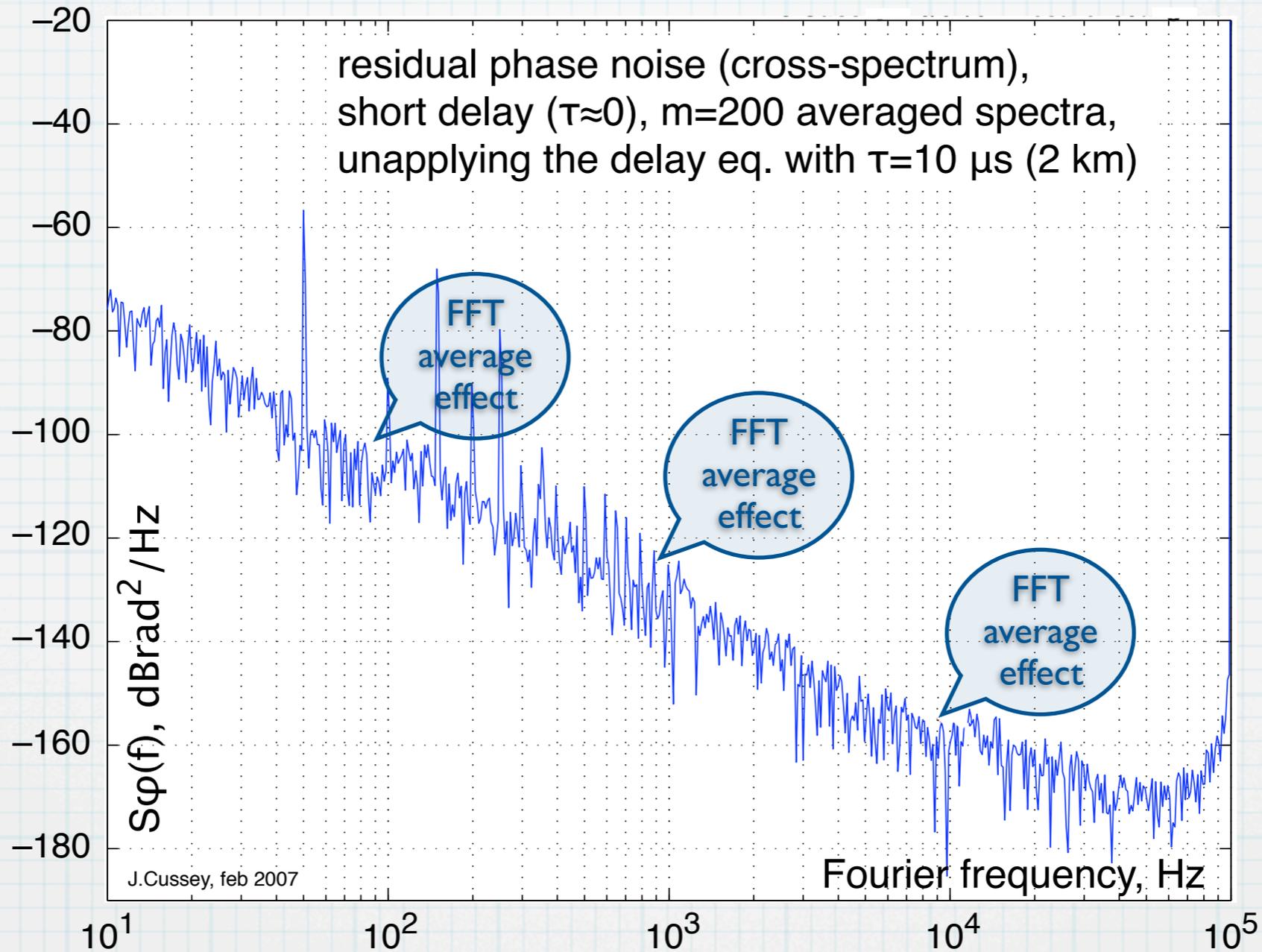
Dual-channel (correlation) instrument

Salik, Yu, Maleki, Rubiola, Proc. Ultrasonics-FCS Joint Conf., Montreal, Aug 2004 p.303-306



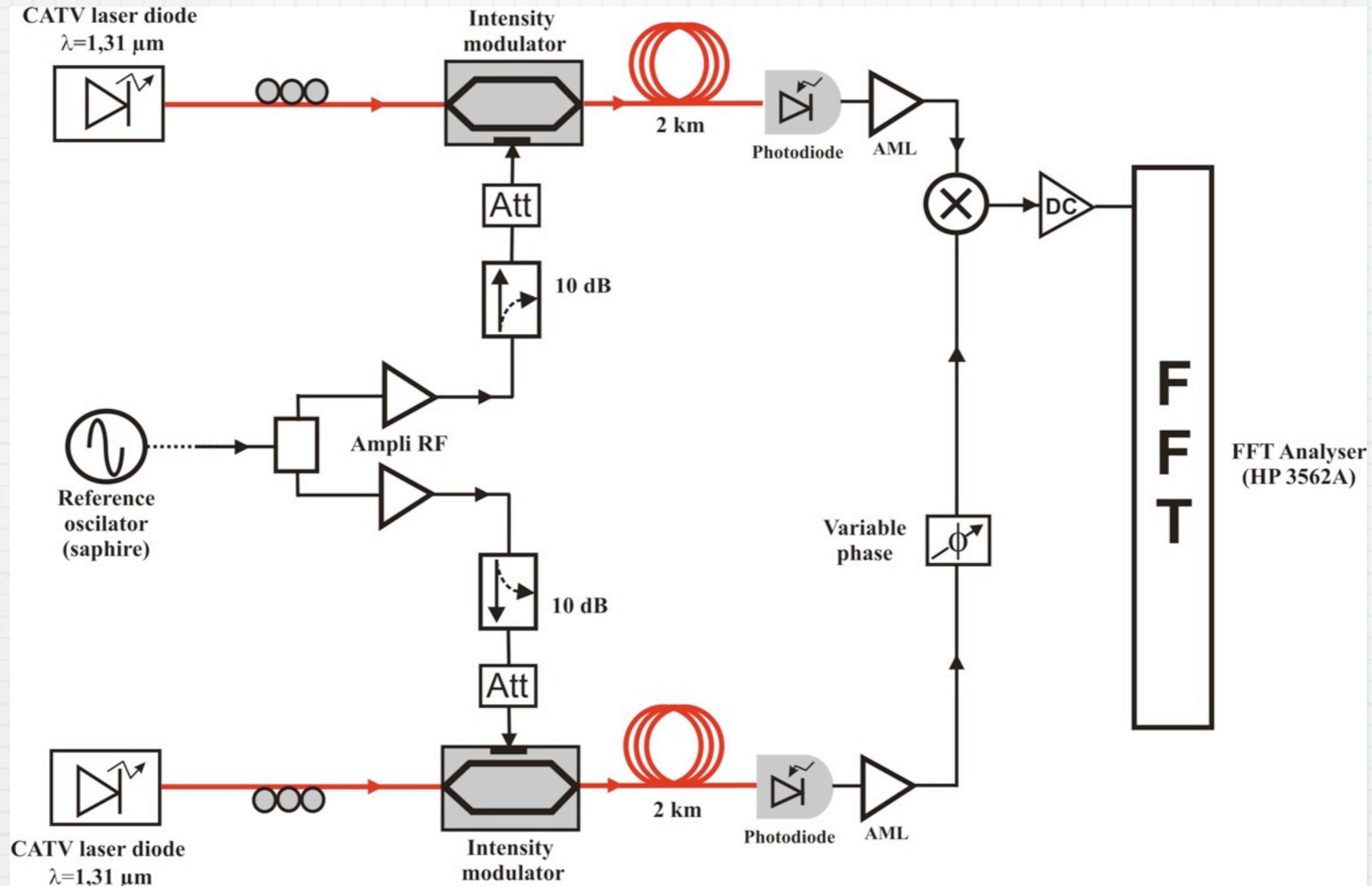
- * uses cross spectrum to reduce the background noise
- * requires two fully independent channels
- * separate lasers for RIN rejection
- * optical-input version is not useful because of the insufficient rejection of AM noise
- * **implemented at the FEMTO-ST Institute**

Dual-channel (correlation) measurement



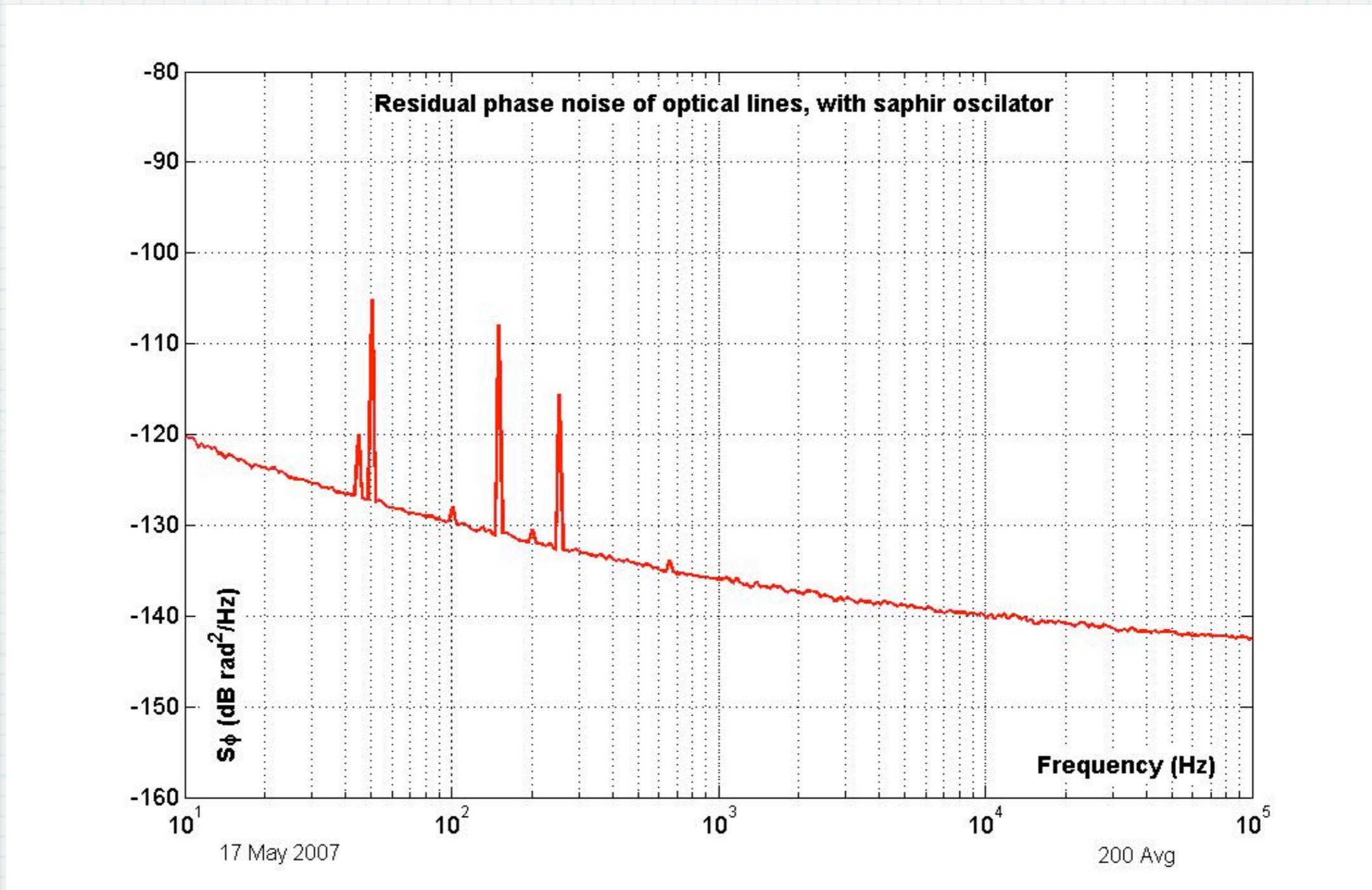
**the residual noise is clearly limited by
the number of averaged spectra, $m=200$**

Measurement of the optical-fiber noise



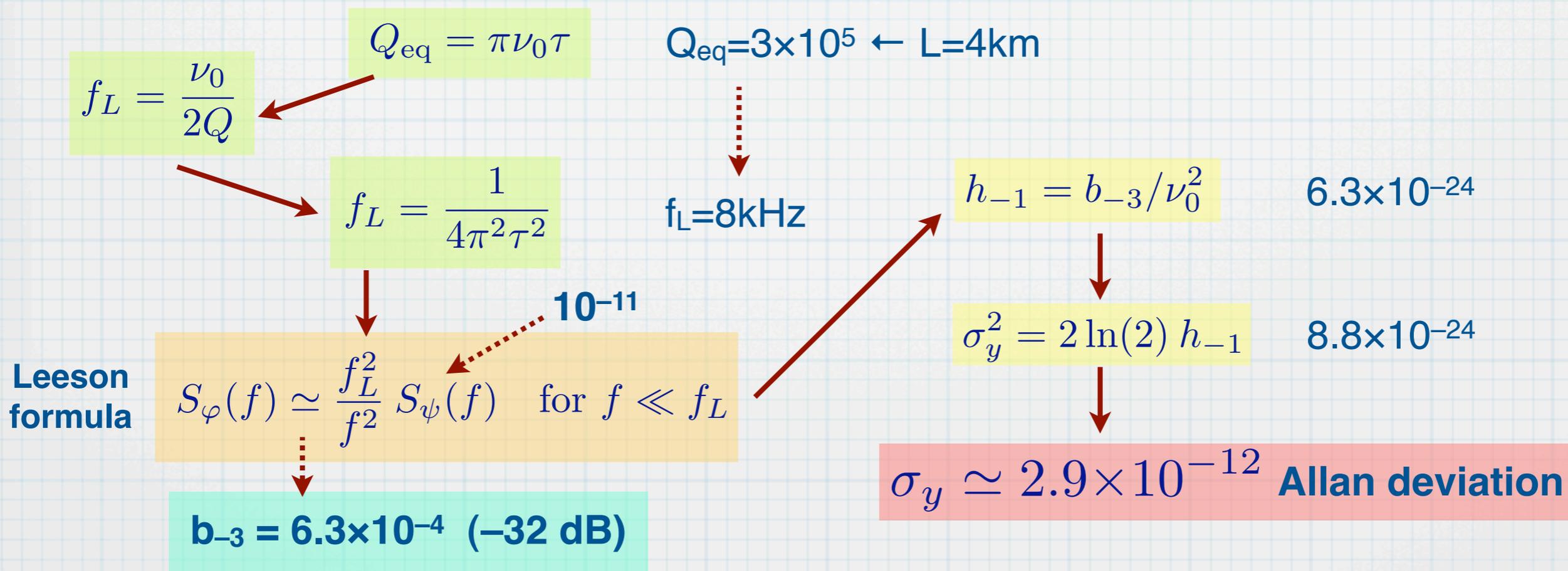
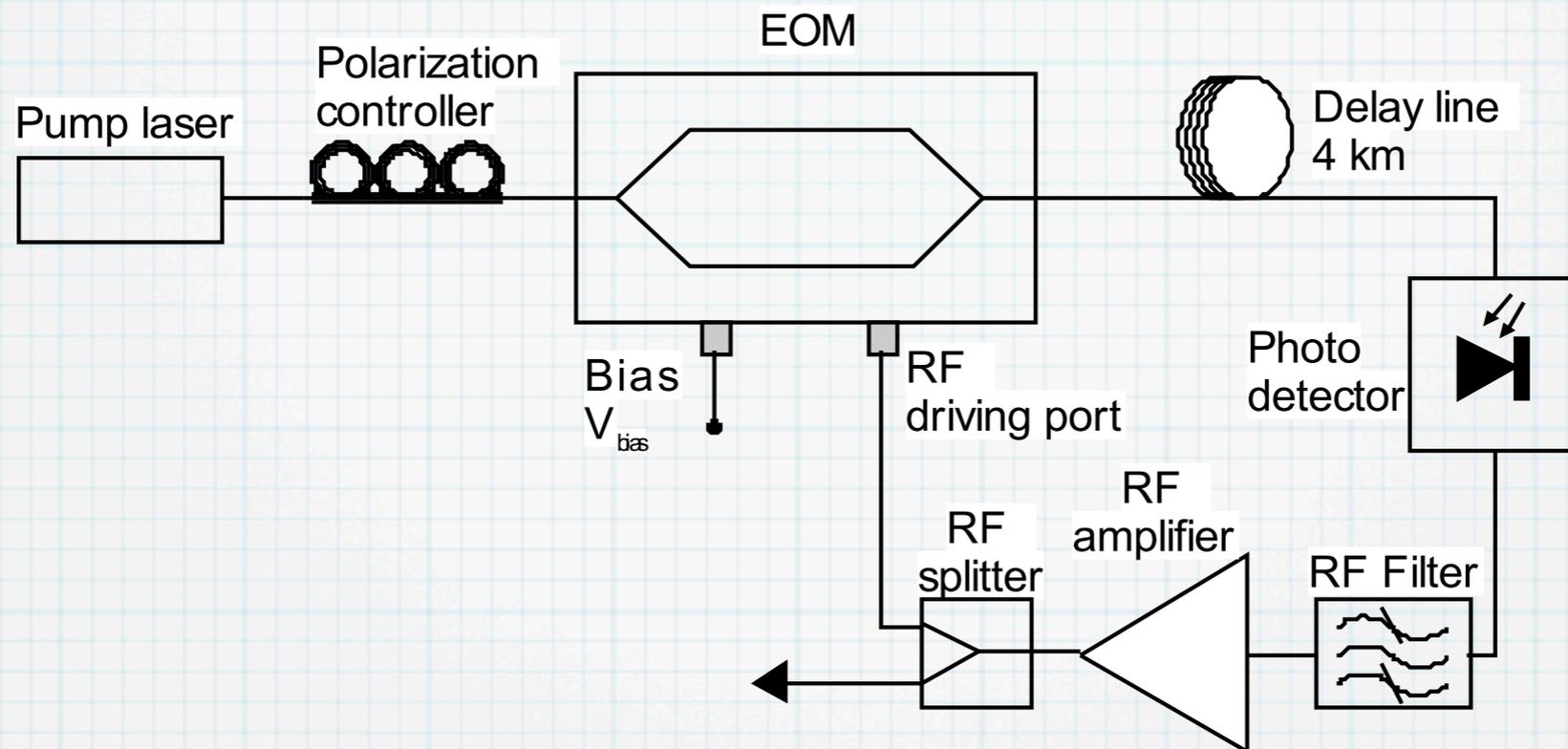
- matching the delays, the oscillator phase noise cancels
- this scheme gives the **total noise**
 $2 \times (\text{ampli} + \text{fiber} + \text{photodiode} + \text{ampli}) + \text{mixer}$
thus it enables only to assess an **upper bound of the fiber noise**

Phase noise of the optical fiber

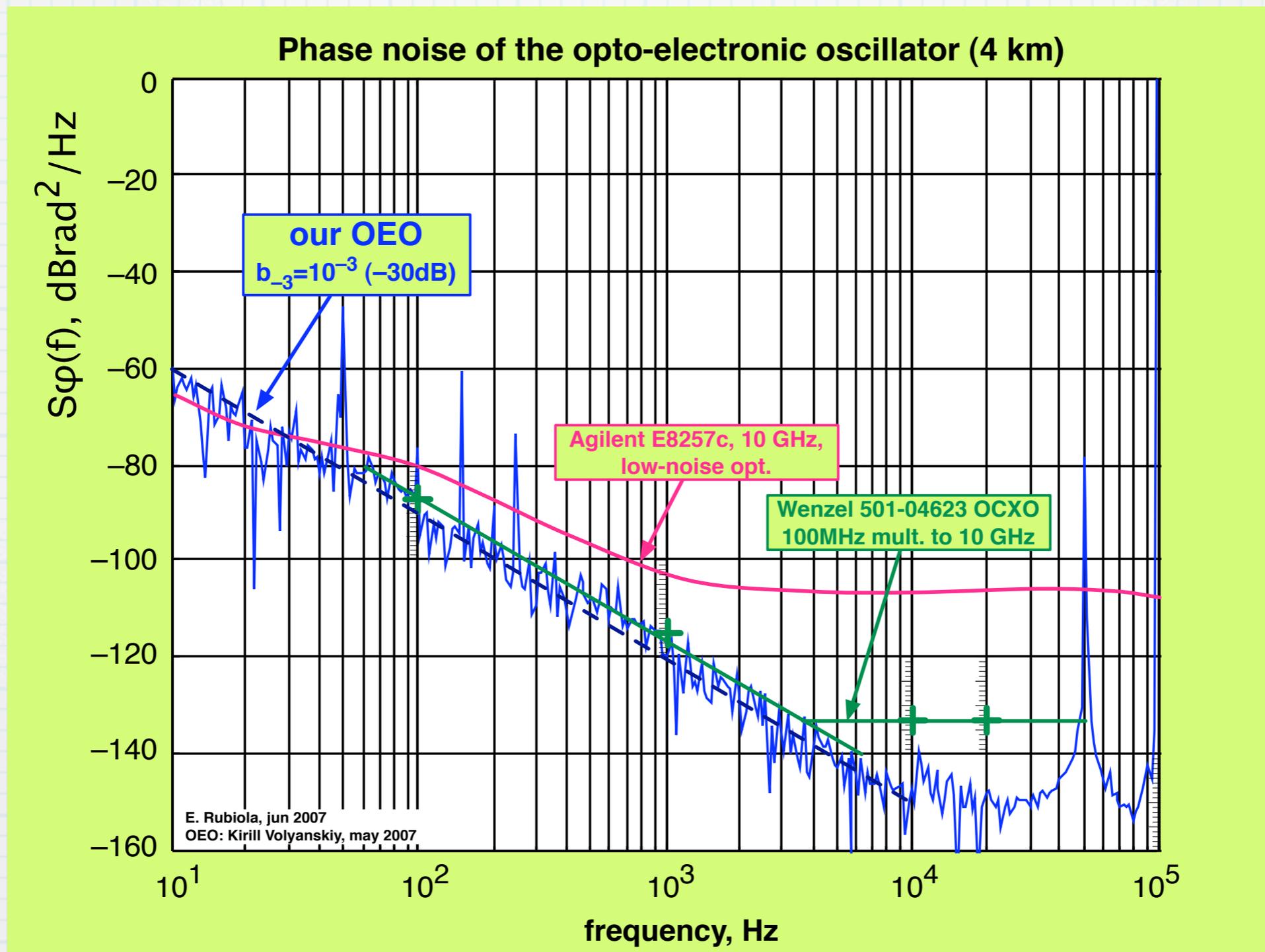


- The method enables only to assess an **upper bound of the fiber noise**
 $b_{-1} \leq 5 \times 10^{-12} \text{ rad}^2/\text{Hz}$ for $L = 2 \text{ km}$ ($-113 \text{ dB rad}^2/\text{Hz}$)
- We believe that this residual noise is the signature of the two GaAs power amplifier that drives the MZ modulator

Delay-line oscillator



Delay-line oscillator



- 1.310 nm DFB CATV laser
- Photodetector DSC 402 ($R = 371 \text{ V/W}$)
- RF filter $\nu_0 = 10 \text{ GHz}$, $Q = 125$
- RF amplifier AML812PNB1901 (gain +22dB)

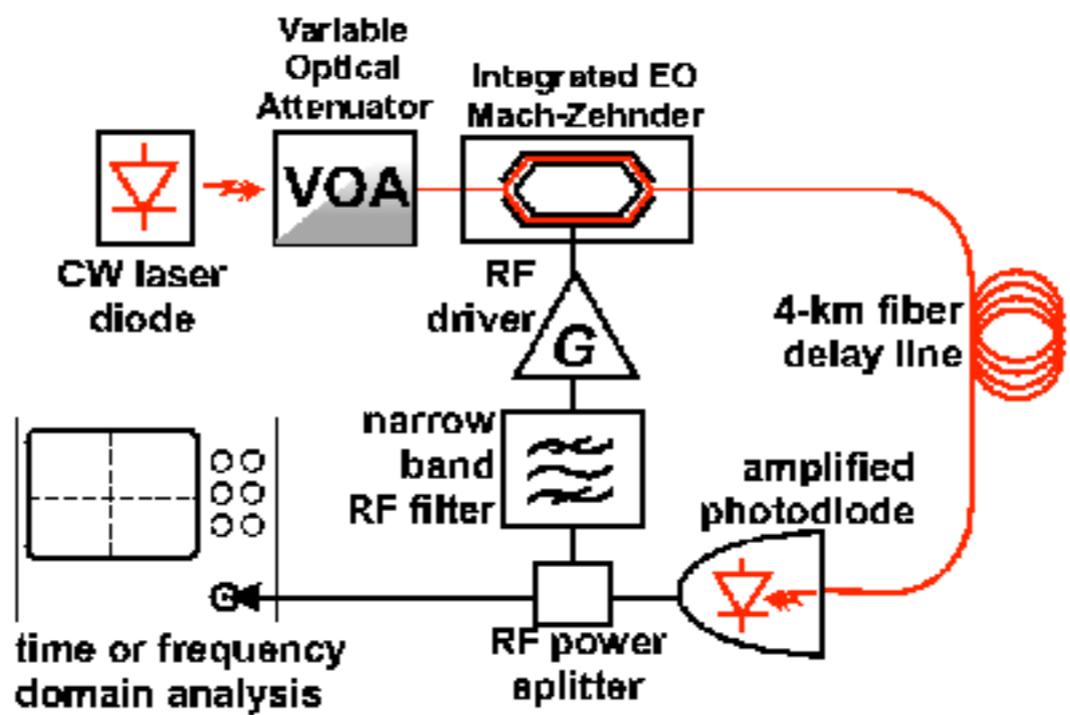
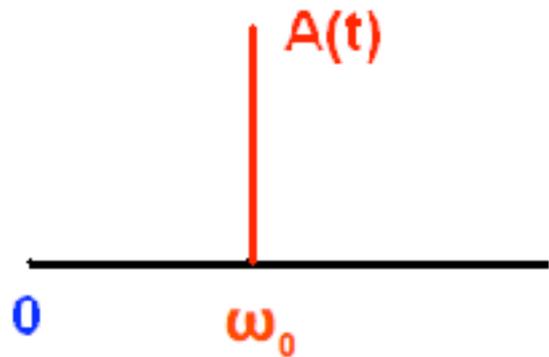
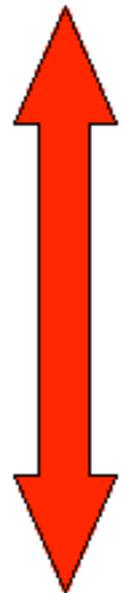
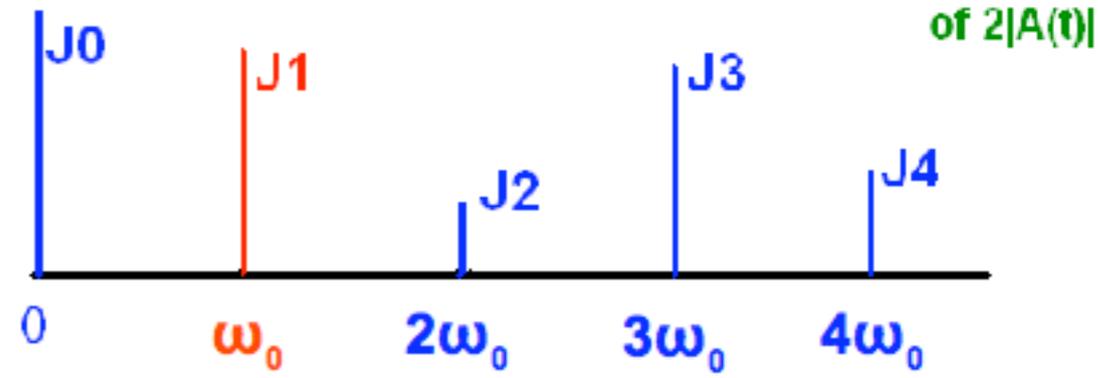
expected phase noise
 $b_{-3} \approx 6.3 \times 10^{-4}$ (-32 dB)

Nonlinear model

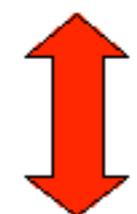
Anger-Jacobi expansion

$$e^{iz \cos \alpha} = \sum_{n=-\infty}^{+\infty} i^n J_n(z) e^{ina}$$

$$\cos^2[x(t) + \phi]$$



Delaying and dephasing by $\sigma_n = n \omega_0 T$



Filtering around ω_0



A complex envelope equation

The complex envelope amplitude of the microwave obeys the equation

$$\dot{A} = -\mu A - 2\mu\gamma e^{-i\sigma} \cdot J_{c1}[2|A_T|] A_T \quad \text{where} \quad J_{c1}(x) = J_1(x)/x \quad \text{is the Bessel-cardinal function}$$

- $\mu = \Delta\omega/2 =$ half-bandwidth of the filter ($= 2\pi \times 10$ MHz)
- $\gamma = \beta \sin 2\phi =$ effective normalized gain (can vary from -5 to 5)
- $\sigma = \Omega_0 T =$ microwave round-trip phase shift

Looks like sinus cardinal, but the maximum is $\frac{1}{2}$ instead of 1

The solutions of interest are:

- $A(t) \equiv 0$ (no oscillations)
- $A(t) \equiv C^{te} \neq 0$ (pure monochromatic)

These states are fixed points of the envelope equation.

We have to study the existence and the stability of the fixed point solutions, particularly for the solution $A(t)=C \neq 0$ which is of great technological interest.

Stability of the oscillating solution

It corresponds to the solution $\mathbf{A}(t) \equiv \mathbf{A}_o \neq \mathbf{0}$ with

$$Jc_1[2|\mathcal{A}_o|] = -\frac{1}{2\gamma} e^{i\sigma}$$

Perturbation equation

$$\delta\dot{\mathcal{A}} = -\mu \cdot \delta\mathcal{A} - 2\mu\gamma \{ Jc_1[2|\mathcal{A}_o|] + 2|\mathcal{A}_o| Jc'_1[2|\mathcal{A}_o|] \} \delta\mathcal{A}_T$$

Stability condition

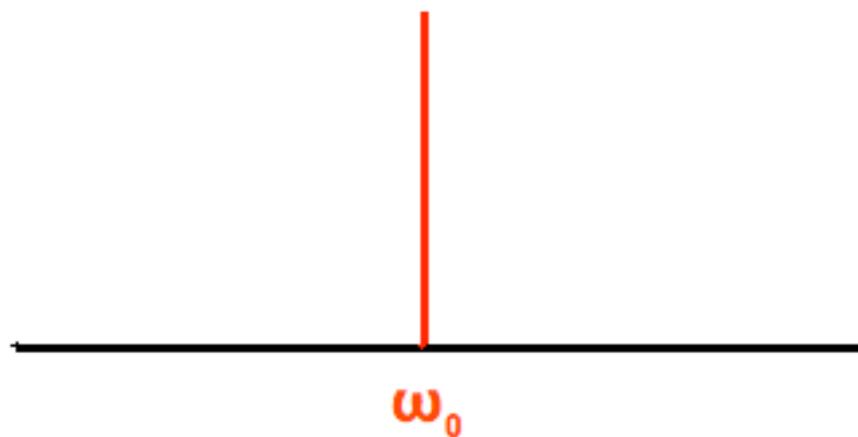
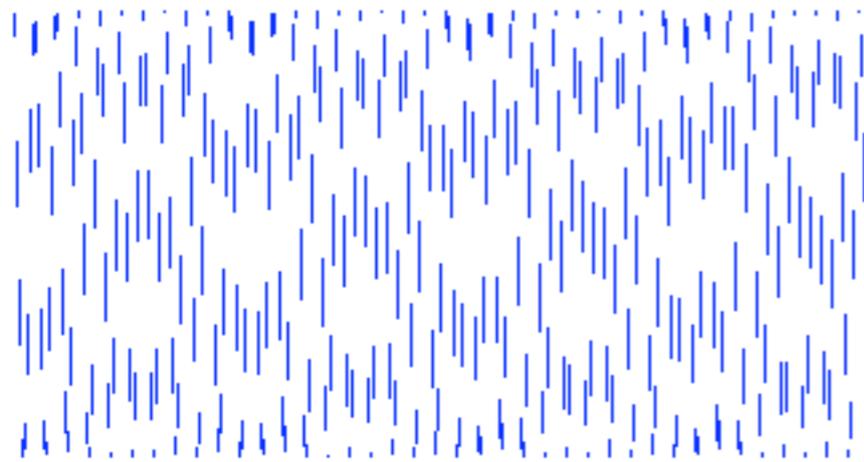
$$\left| \frac{1}{2} + \frac{|\mathcal{A}_o| Jc'_1[2|\mathcal{A}_o|]}{Jc_1[2|\mathcal{A}_o|]} \right| < \frac{1}{2} \text{ fulfilled when } 1 < \gamma < 2.3, \text{ when } e^{-i\sigma} = -1$$

What does occur beyond 2.3 ???

A Hopf bifurcation

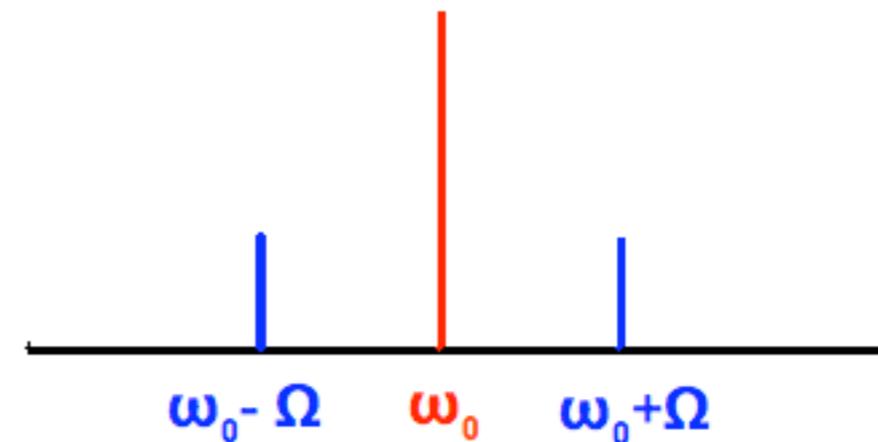
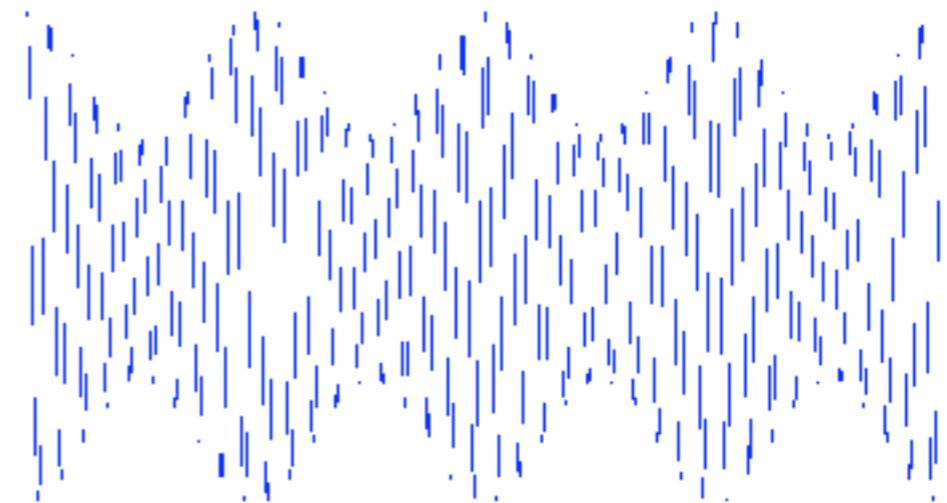
Gain < 2.3

$$A = A_0$$



Gain > 2.3

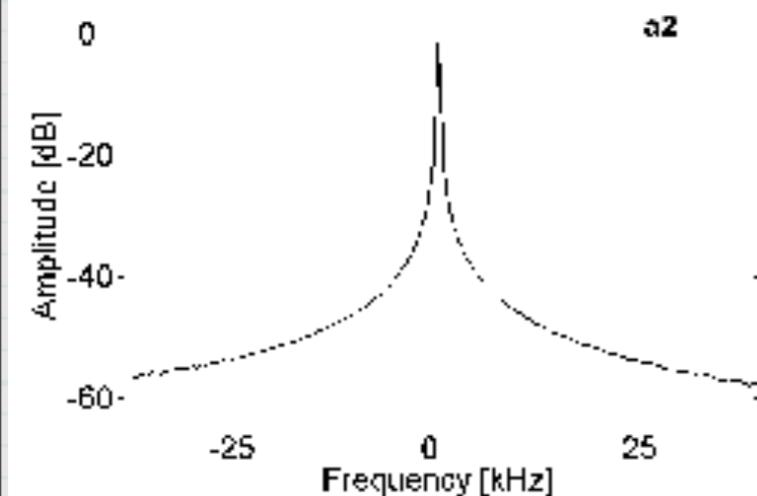
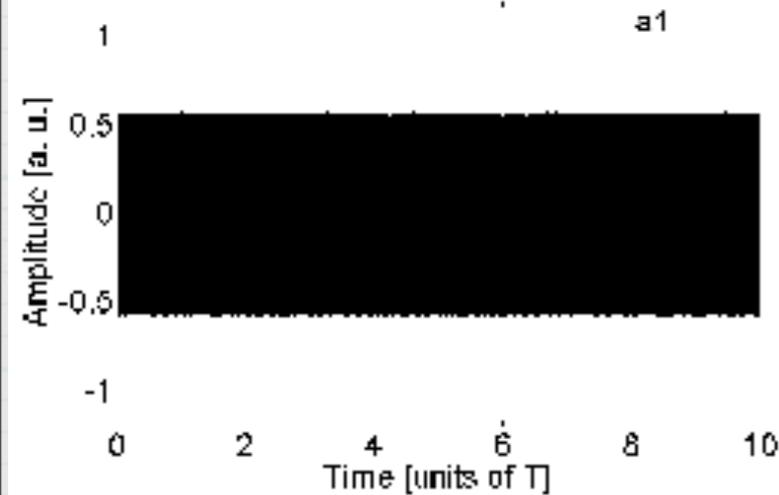
$$A = A_0 + a_0 \exp[i \Omega t]$$



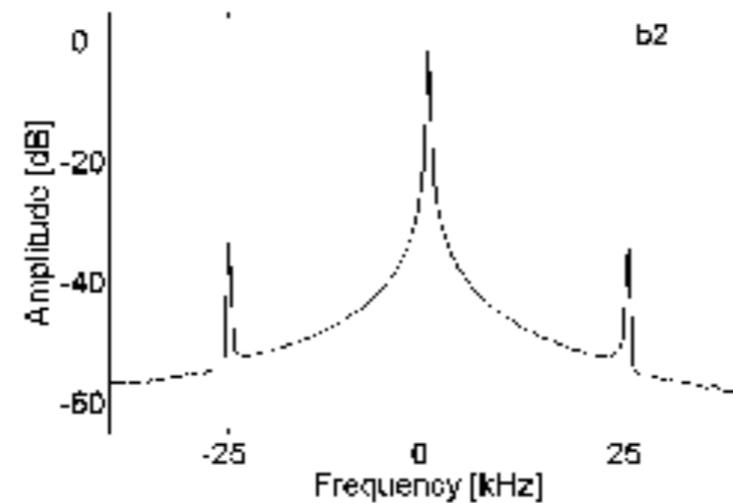
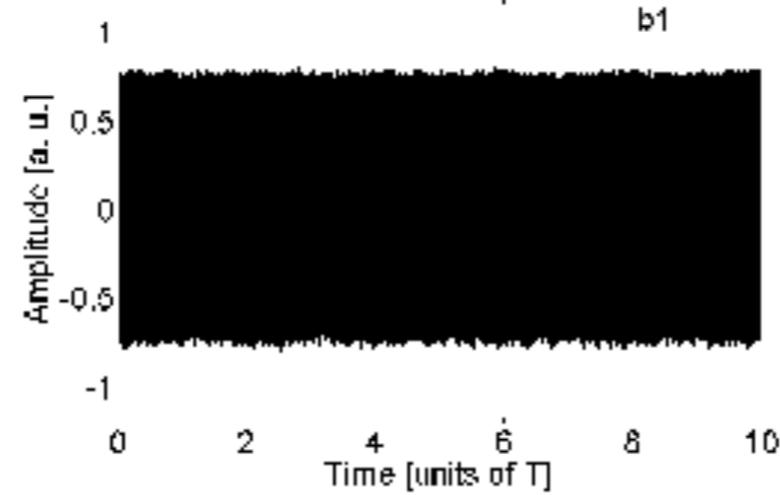
The bifurcation at $\gamma=2.3$ should qualitatively modify the Fourier spectrum of OEOs

Hopf bifurcation, observed

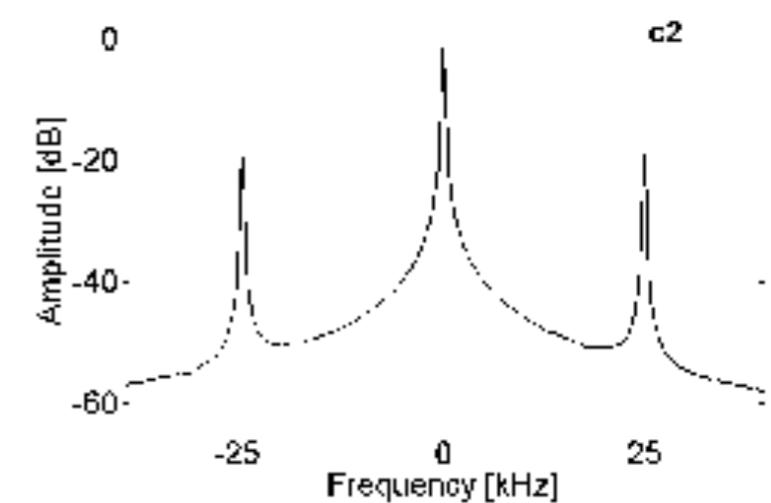
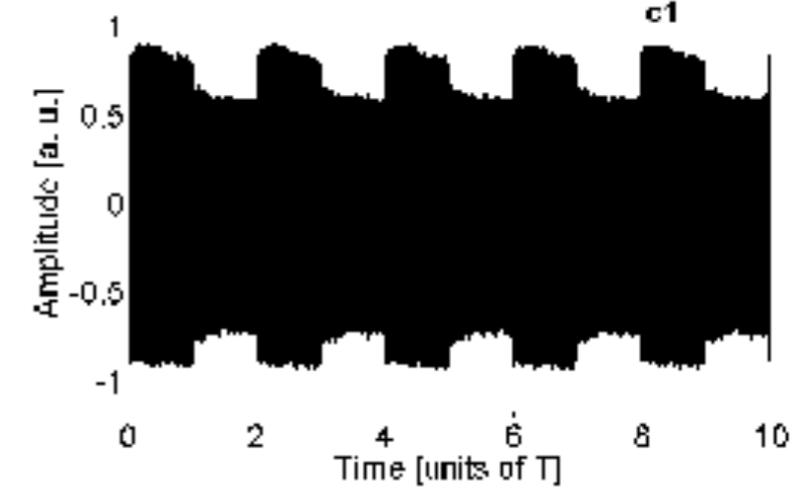
Before the bifurcation



At the bifurcation



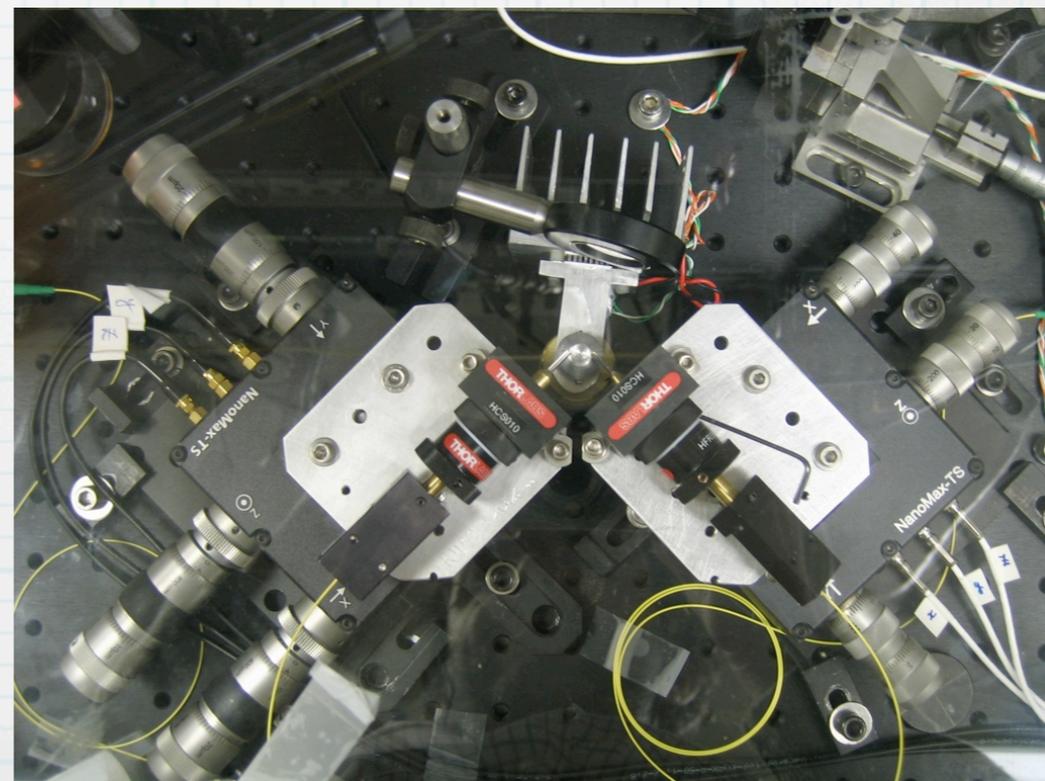
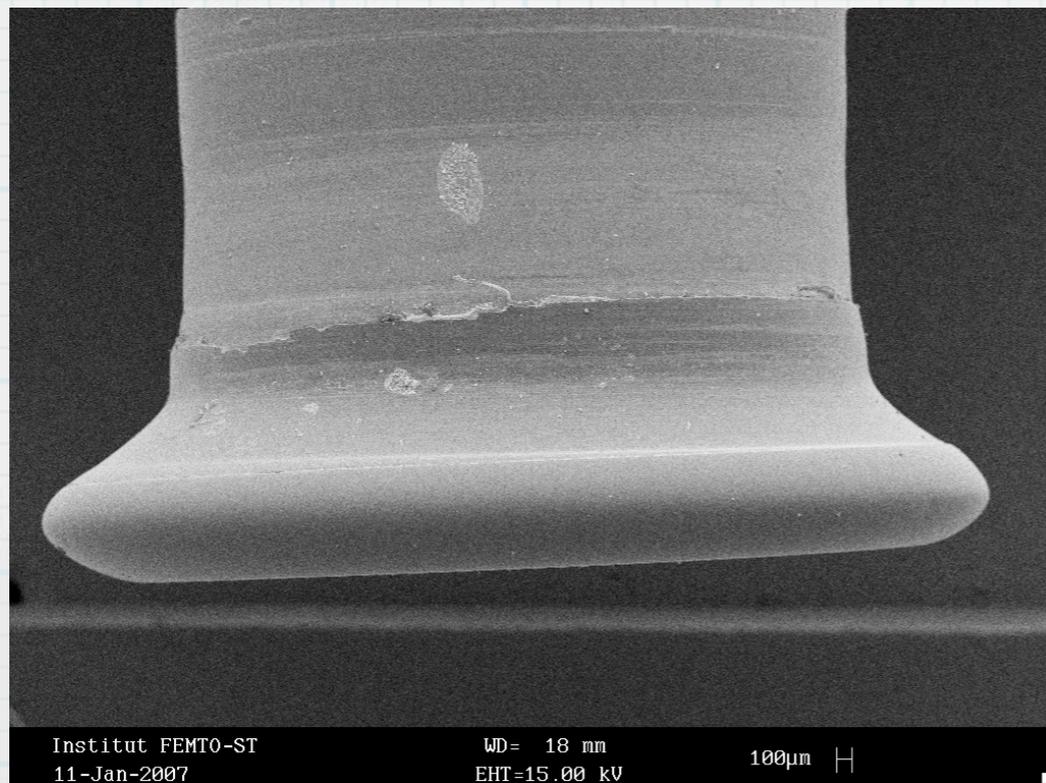
After the bifurcation

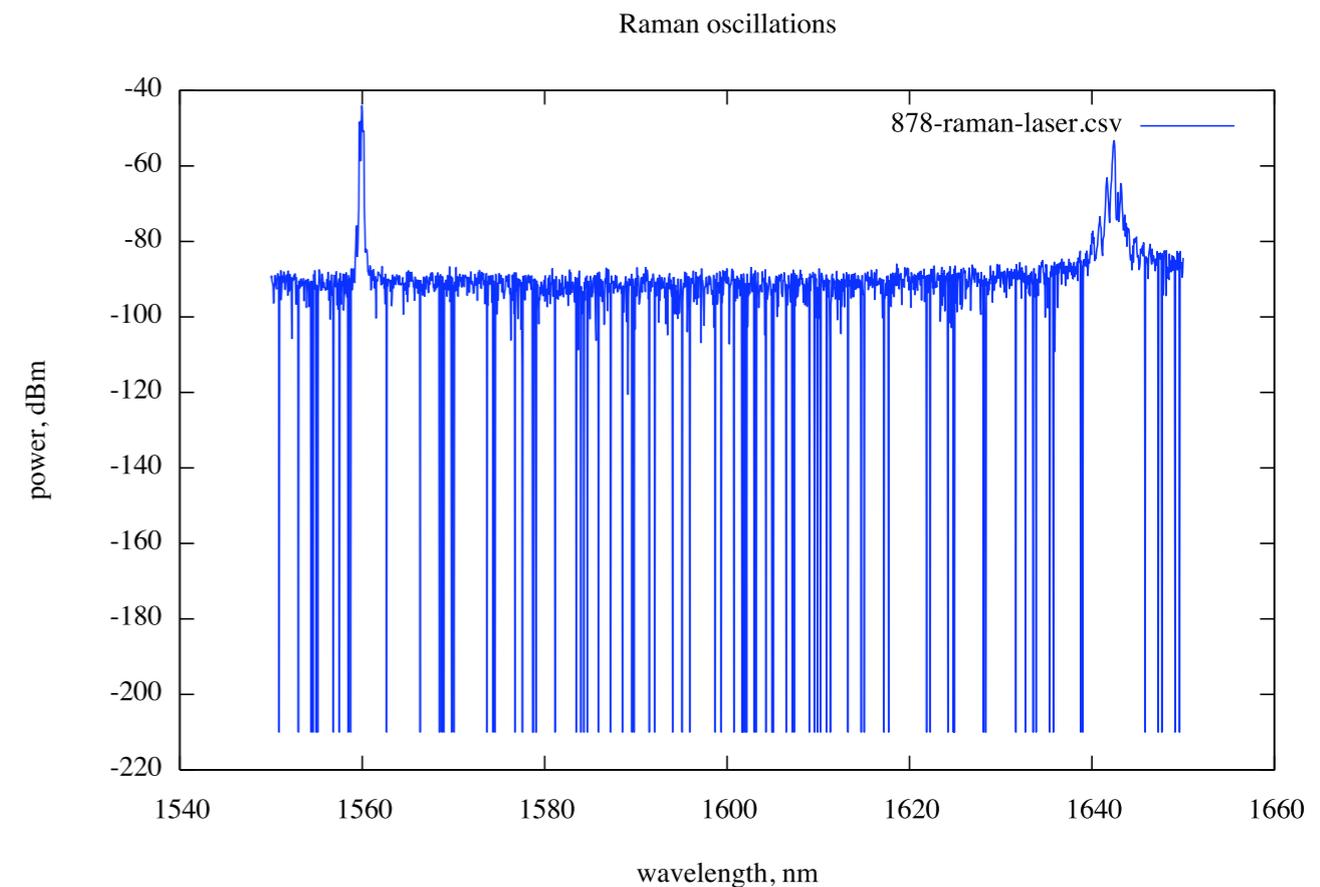
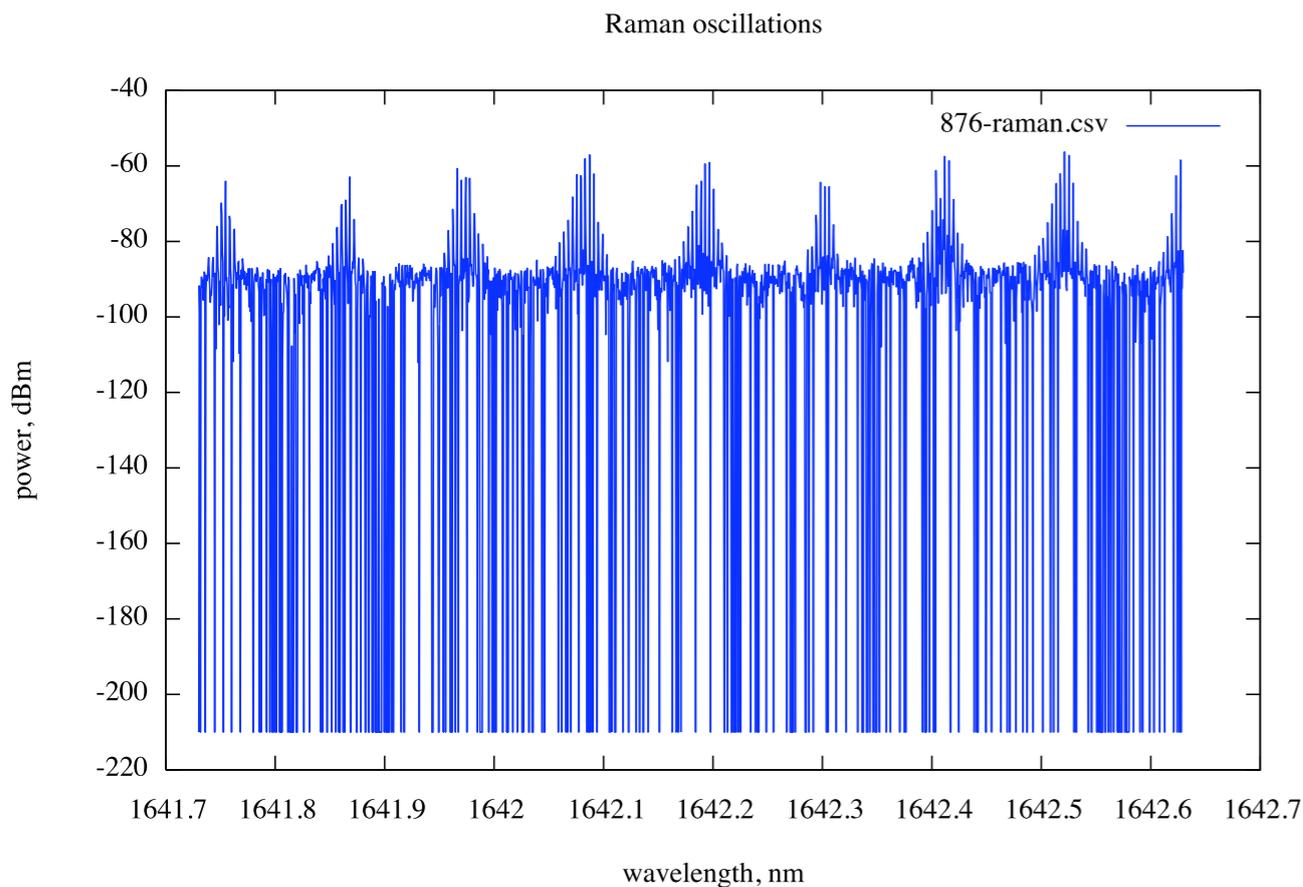


The Hopf bifurcation leads to the emergence of robust modulation side-peaks in the Fourier spectrum, which may drastically affect the phase noise performance of OEOs

Small resonators

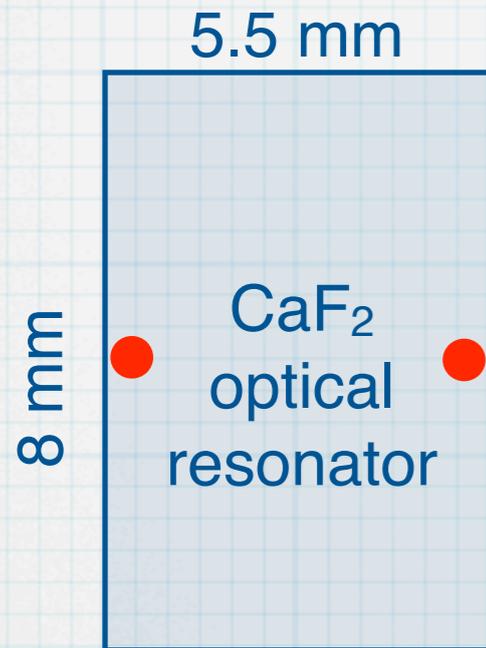
- * Technology development in progress (quartz CaF_2 , MgF_2)
- * A bunch of technical problems (and Ryad Bendoula left)
- * Taper coupling still problematic
- * some interesting phenomena observed





- **The Raman amplification is a quantum phenomenon of nonlinear origin that involves optical phonons.**
- **An amplifier inserted in a high-Q cavity turns into an oscillator, like masers and lasers.**
- **Oscillation threshold $\sim 1/Q^2$**
- **In CaF₂ pumped at 1.56 μm , Raman oscillation occurs at 1.64 μm**
- **Due to the large linewidth, the Raman oscillation appears as a bunch of (noisy) spectral lines spaced by the FSR (12 GHz, or 100 pm in our case)**
- **Raman phonons modulate the optical properties of the crystal, which induces noise at the pump frequency (1.56 μm)**

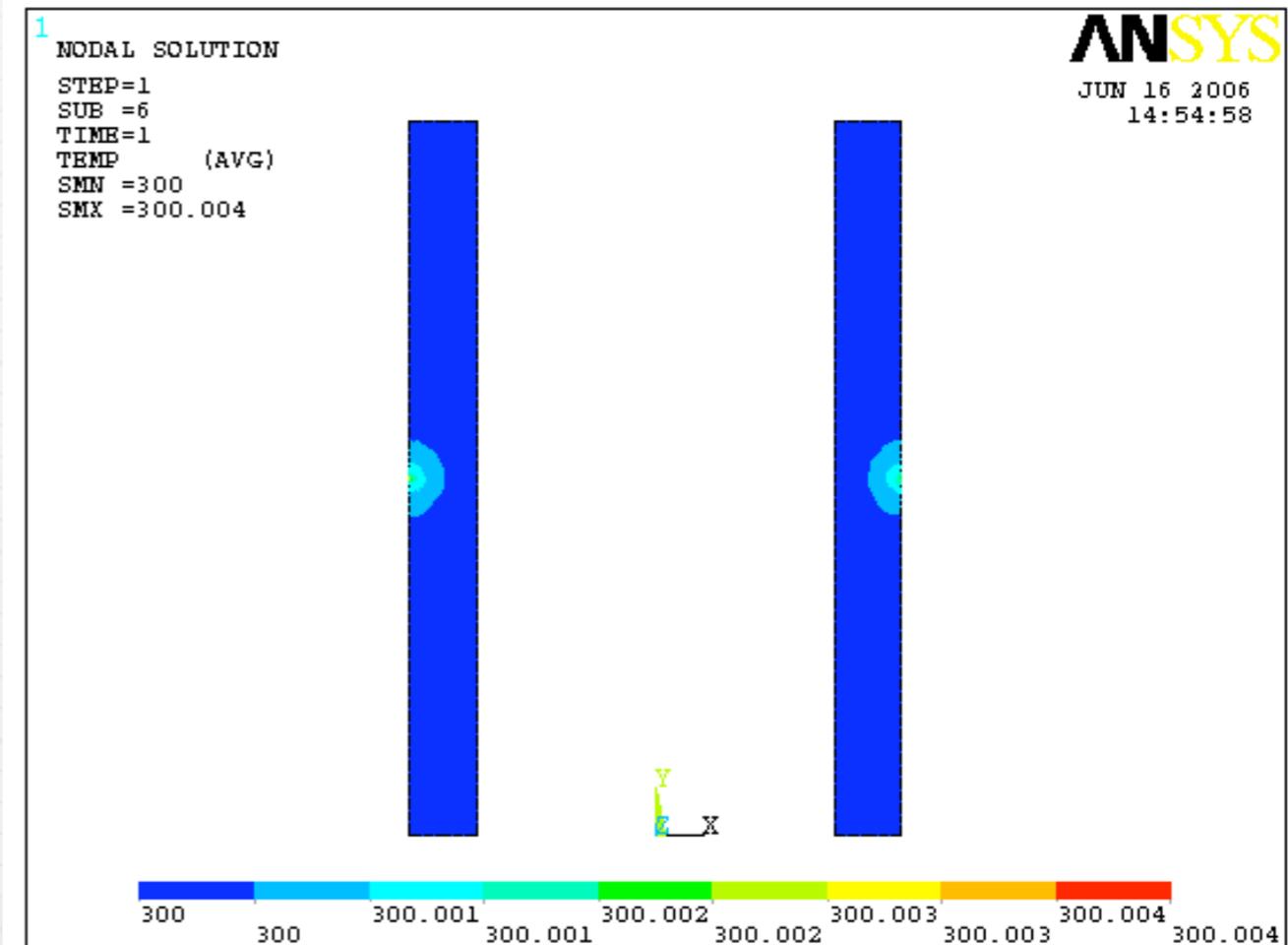
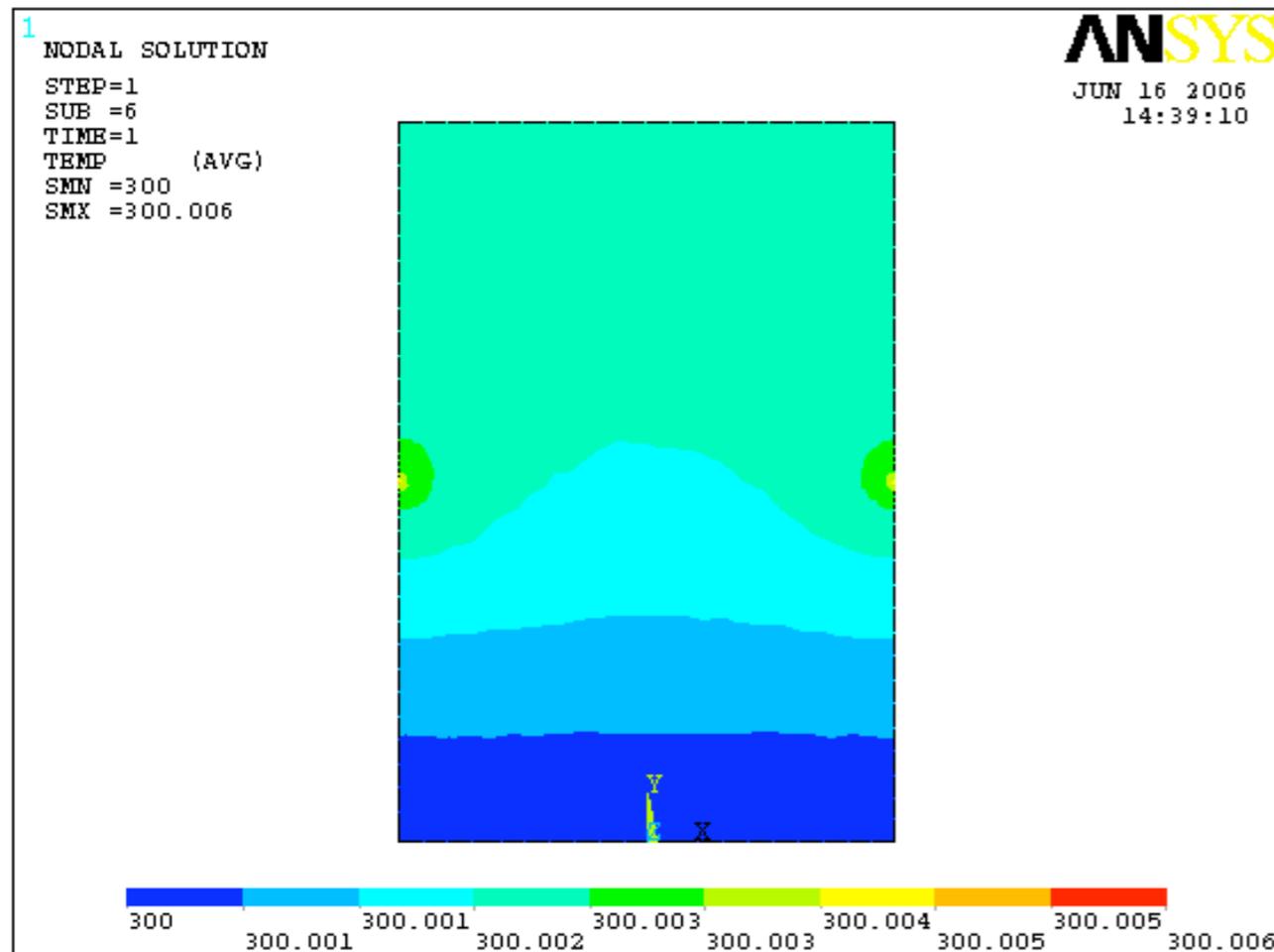
High temperature gradient



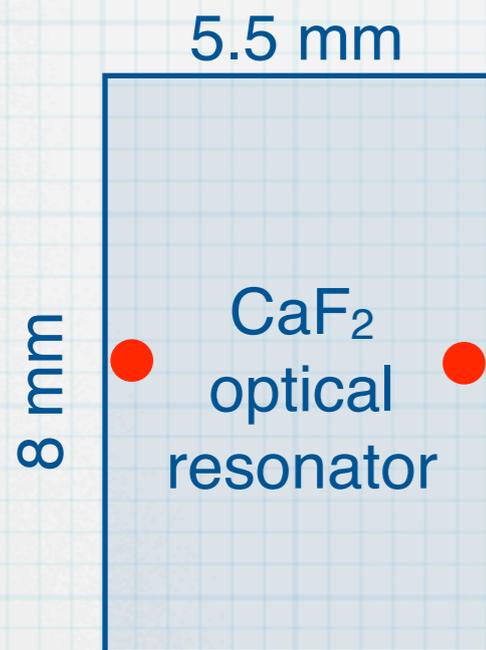
- cross section of the field region $1 \mu\text{m}^2$
- CaF_2 thermal conductivity 9.5 W/mK
- dissipated power $300 \mu\text{W}$
- wavelength $1.56 \mu\text{m}$
- air temperature 300 K
- still air thermal conductivity $10 \text{ W/m}^2\text{K}$
- **simplification: the heat flow from the mode region is uniform**

bottom plane at a reference temperature

inner bore at a reference temperature



Thermal effect on frequency

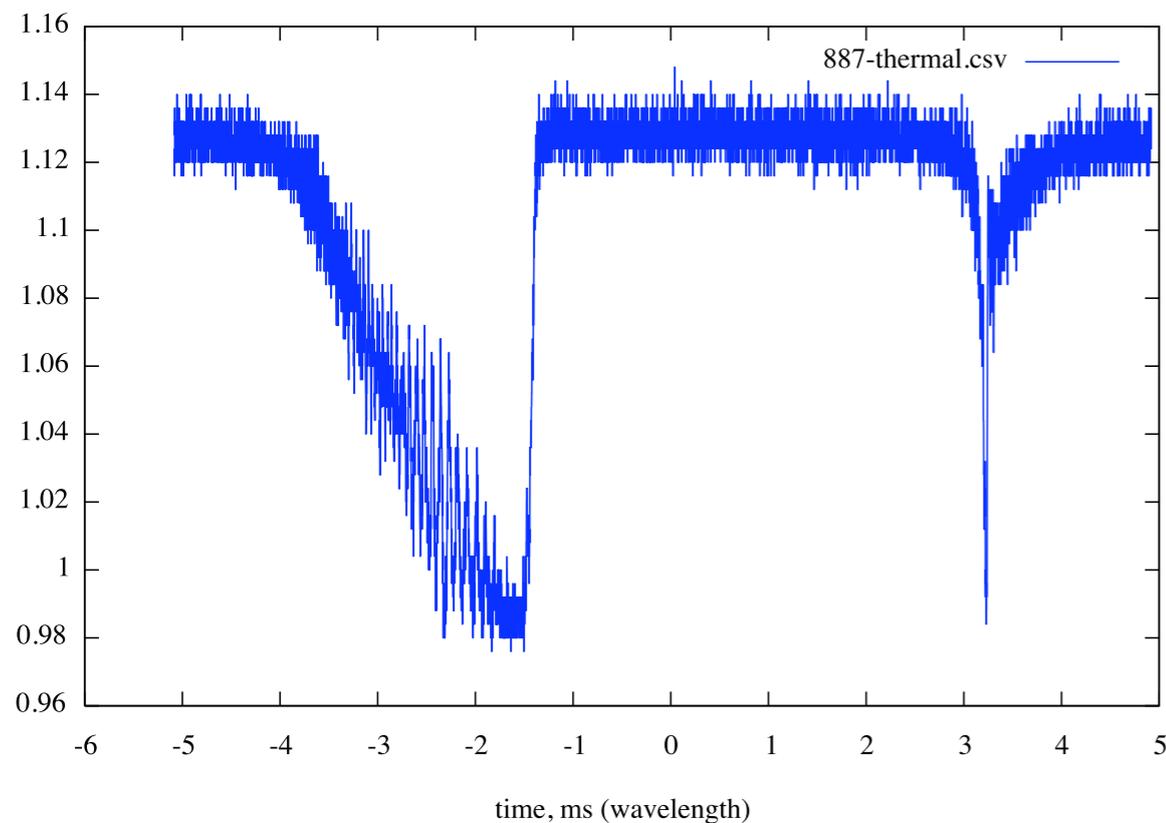


- wavelength 1.56 μm ($\nu_0=192$ THz)
- $Q=5 \times 10^9 \rightarrow \text{BW}=40$ kHz
- a dissipated power of 300 μW shifts the resonant frequency by 1.2 MHz (6×10^{-9}), i.e., 37.5 x BW
- time scale about 60 μs
- $Q > 10^{11}$ is possible with CaF₂ and other crystals!!

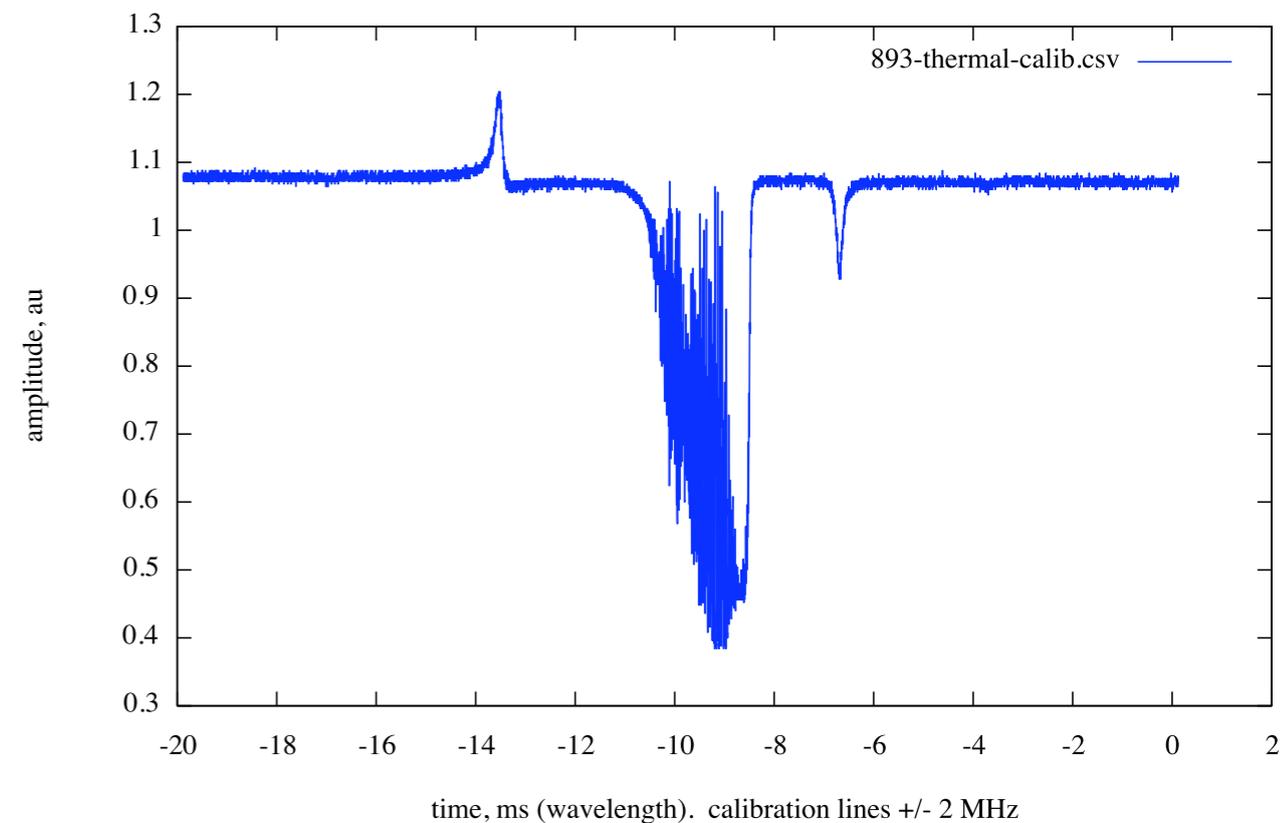
laser scan

calibration (2 MHz phase modulation)

Thermal effect in a CaF2 resonator



Thermal effect in a CaF2 resonator (calibration)



Low-power oscillator operation

Assume: $\lambda = 1560 \text{ nm}$ $R = 50 \text{ Ohm}$
 $\rho = 0.8 \text{ A/W}$ $(P_\lambda)_{\text{peak}} = 2 \times 10^{-5} \text{ W}$ (20 μW)

Shot noise (m=1)

$$I_{RMS} = \frac{1}{\sqrt{2}} \rho \bar{P}_\lambda$$

$$S_I = 2q\bar{I} = 2q \rho \bar{P}_\lambda$$

$$SNR = \frac{1}{4} \frac{\rho \bar{P}_\lambda}{q}$$

Thermal noise (m=1)

$$I_{RMS} = \frac{1}{\sqrt{2}} \rho \bar{P}_\lambda$$

$$S_I = \frac{4kT}{R} \quad \text{or} \quad \frac{4FkT}{R}$$

$$SNR = \frac{1}{8} \frac{\rho^2 \bar{P}_\lambda^2 R}{kT}$$

In practice, $-131 \text{ dBrad}^2/\text{Hz}$

In practice, $-110 \text{ dBrad}^2/\text{Hz}$
with $F=0 \text{ dB}$ (!!!)

- Thermal noise is dominant: below threshold, $SNR \sim 1/P_\lambda^2$
- Thermal noise can be reduced (10 dB or more?) using VGND amplifiers
- What about flicker of photodetectors with integrated VGND amplifier?
- Dramatic impact on the (phase) noise floor